

# **Ground Sense Comparator**

BA8391G BA10393F BA10339 Series BA2903 Series BA2901 Series

#### **General Description**

General purpose BA8391G/BA10393F/BA10339xx and high reliability BA2903xxxx/BA2901xxx integrate one, two or four independent high gain voltage comparator.

Operating supply voltage range of BA8391G/BA1039 3F/BA2903xxxx/BA2901xxx is wide(2V to 36V). And can be used in a variety of applications because current consumption is small. BA2903Wxx is a low input offset voltage products.(2mV max)

#### **Features**

- Operable with a Single Power Supply
- Wide Operating Supply Voltage
- Standard Pin Assignments
- Input and Output are Ground Sense Operated
- Open Collector
- Wide Temperature Range

#### **Application**

- General Use
- Current Monitor
- Battery Monitor
- Multi vibrator

#### **Key Specifications**

■ Operating Supply Voltage(Single Supply):

BA8391G/BA10393F +2.0V to +36.0V BA2903xxxx/BA2901xxx +2.0V to +36.0V BA10339xx +3.0V to +36.0V

■ Operating Supply Voltage(Split Supply):

BA8391G/BA10393F ±1.0V to ±18.0V BA2903xxxx/BA2901xxx ±1.0V to ±18.0V BA10339xx ±1.5V to ±18.0V

■ Temperature Range:

BA8391G/BA10393F/BA10339xx
BA2903Sxxx/BA2901Sxx
BA2903xxx/BA2901xx
-40°C to +85°C
-40°C to +105°C
-40°C to +125°C

■ Input Offset Voltage:

BA2903Sxxx/BA2901Sxx 7mV(Max)
BA8391G/BA2903xxx/BA2901xx 7mV(Max)
BA10393F/BA10339xx 5mV(Max)
BA2903Wxx 2mV(Max)

 Packages
 W(Typ) x D(Typ) x H(Max)

 SSOP5
 2.90mm x 2.80mm x 1.25mm

 SOP8
 5.00mm x 6.20mm x 1.71mm

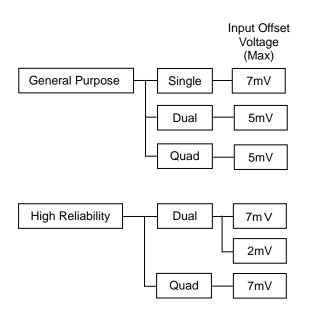
 SSOP-B8
 3.00mm x 6.40mm x 1.35mm

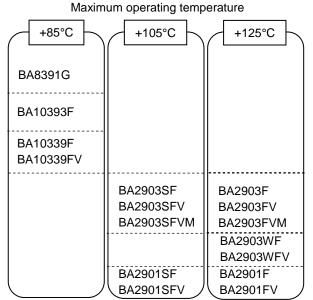
 MSOP8
 2.90mm x 4.00mm x 0.90mm

 SOP14
 8.70mm x 6.20mm x 1.71mm

 SSOP-B14
 5.00mm x 6.40mm x 1.35mm

#### **Selection Guide**





#### **Simplified Schematic**

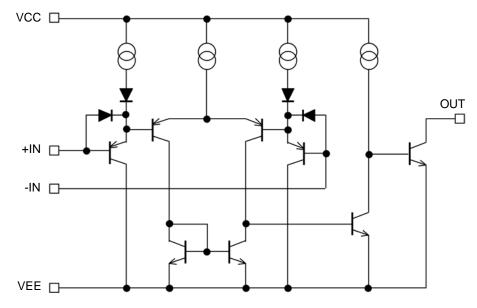
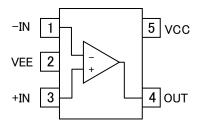


Figure 1. Simplified Schematic (one channel only)

## **Pin Configuration**

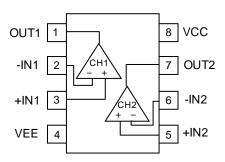
BA8391G: SSOP5



Pin No.	Pin Name				
1	-IN				
2	VEE				
3	+IN				
4	OUT				
5	VCC				

BA10393F, BA2903SF, BA2903F, BA2903WF: SOP8 BA2903SFV, BA2903FV, BA2903WFV: SSOP-B8

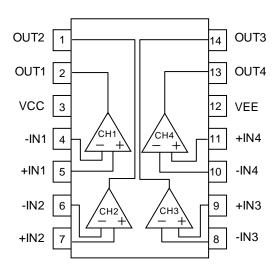
BA2903SFVM,BA2903FVM: MSOP8



Pin No.	Pin Name				
1	OUT1				
2	-IN1				
3	+IN1				
4	VEE				
5	+IN2				
6	-IN2				
7	OUT2				
8	VCC				

#### Pin Configuration - continued

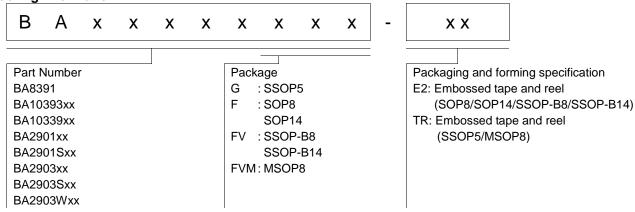
BA10339F, BA2901SF, BA2901F : SOP14 BA10339FV, BA2901SFV, BA2901FV : SSOP-B14



Pin No.	Pin Name					
1	OUT2					
2	OUT1					
3	VCC					
4	-IN1					
5	+IN1					
6	-IN2					
7	+IN2					
8	-IN3					
9	+IN3					
10	-IN4					
11	+IN4					
12	VEE					
13	OUT4					
14	OUT3					

Package										
SSOP5	SOP8	SSOP-B8	MSOP8	SOP14	SSOP-B14					
BA8391G	BA10393F BA2903SF BA2903F BA2903WF	BA2903SFV BA2903FV BA2903WFV	BA2903SFVM BA2903FVM	BA10339F BA2901SF BA2901F	BA10339FV BA2901SFV BA2901FV					

**Ordering Information** 



Line-up

Operating Temperature Range	Input Offset Voltage (Max)	Supply Current (Typ)	Pa	ackage	Orderable Part Number
	7mV	0.3mA	SSOP5	Reel of 3000	BA8391G-TR
-40°C to +85°C		0.4mA	SOP8	Reel of 2500	BA10393F-E2
-40°C to +85°C	5mV	0.0 1	SOP14	Reel of 2500	BA10339F-E2
		0.8mA	SSOP-B14	Reel of 2500	BA10339FV-E2
			SOP8	Reel of 2500	BA2903SF-E2
	- V	0.6mA 0.8mA	SSOP-B8	Reel of 2500	BA2903SFV-E2
-40°C to +105°C			MSOP8	Reel of 3000	BA2903SFVM-TR
			SOP14	Reel of 2500	BA2901SF-E2
	7mV		SSOP-B14	Reel of 2500	BA2901SFV-E2
	]		SOP8	Reel of 2500	BA2903F-E2
			SSOP-B8	Reel of 2500	BA2903FV-E2
		0.6mA	MSOP8	Reel of 3000	BA2903FVM-TR
-40°C to +125°C	20001/		SOP8	Reel of 2500	BA2903WF-E2
	2mV		SSOP-B8	Reel of 2500	BA2903WFV-E2
	7\/	0.0 1	SOP14	Reel of 2500	BA2901F-E2
	7mV	0.8mA	SSOP-B14	Reel of 2500	BA2901FV-E2

**Absolute Maximum Ratings** (Ta=25°C)

Doromotor	Symbol		Rating	Unit		
Parameter	Syl	IIDOI	BA8391G	Unit		
Supply Voltage	VCC	-VEE	+36	V		
Power Dissipation	P <sub>D</sub>	SSOP5	0.67 <sup>(Note1,2)</sup>	W		
Differential Input Voltage (Note 3)	V <sub>ID</sub>		+36	V		
Input Common-mode Voltage Range	V <sub>ICM</sub>		(VEE-0.3) to (VEE+36)	V		
Input Current (Note 4)		lı	-10	mA		
Operating Supply Voltage	V	opr	+2.0 to +36.0 (±1.0 to ±18.0)	V		
Operating Temperature Range	T <sub>opr</sub>		T <sub>opr</sub>		-40 to +85	°C
Storage Temperature Range	$T_{stg}$		-55 to +150	°C		
Maximum Junction Temperature	$T_{jmax}$		+150	°C		

<sup>(</sup>Note 1) To use at temperature above T<sub>A</sub>=25°C reduce 5.4mW.

Caution: Operating the IC over the absolute maximum ratings may damage the IC. The damage can either be a short circuit between pins or an open circuit between pins and the internal circuitry. Therefore, it is important to consider circuit protection measures, such as adding a fuse, in case the IC is operated over the absolute maximum ratings.

<sup>(</sup>Note 2) Mounted on a FR4 glass epoxy PCB(70mm×70mm×1.6mm).

<sup>(</sup>Note 3) The voltage difference between inverting input and non-inverting input is the differential input voltage.

Then input terminal voltage is set to more than VEE.

<sup>(</sup>Note 4) Excessive input current will flow if a differential input voltage in excess of approximately 0.6V is applied between the input unless some limiting resistance is used.

**Absolute Maximum Ratings - continued** 

Darameter		Cumbal	Rating			
Parameter		Symbol	BA10393F	BA10339xx	Unit	
Supply Voltage		VCC-VEE	+3	36	V	
		SOP8	0.62 (Note 5,8)	-		
Power Dissipation	P <sub>D</sub>	SOP14	-	0.49 (Note 6,8)	W	
		SSOP-B14	-	0.70 (Note 7,8)		
Differential Input Voltage <sup>(Note 9)</sup>		$V_{ID}$	(VEE to VCC)			
Input Common-mode Voltage Range		V <sub>ICM</sub>	(VEE-0.3) to VCC			
Input Current <sup>(Note 10)</sup>		l <sub>l</sub>	-10			
Operating Supply Voltage		V <sub>opr</sub>	+2.0 to +36.0 (±1.0 to ±18.0)	+3.0 to +36.0 (±1.5 to ±18.0)	V	
Operating Temperature Range		$T_{opr}$	-40 to +85			
Storage Temperature Range		T <sub>stg</sub>	-55 to +125			
Maximum Junction Temperature		T <sub>jmax</sub>	+125			

To use at temperature above T<sub>A</sub>=25°C reduce 6.2mW

Caution: Operating the IC over the absolute maximum ratings may damage the IC. The damage can either be a short circuit between pins or an open circuit between pins and the internal circuitry. Therefore, it is important to consider circuit protection measures, such as adding a fuse, in case the IC is operated over the absolute maximum ratings.

Dorometer	Doromotor Symbol		Rating						
Parameter		Symbol	BA2903Sxxx	BA2901Sxx	BA2903xxx	BA2901xx	Unit		
Supply Voltage	١	/CC-VEE		+:	36	,	V		
		SOP8	0.77 (Note 11,16)	-	0.77 (Note 11,16)	-			
		SSOP-B8	0.68 (Note 12,16)	-	0.68 (Note 12,16)	-	W		
Power Dissipation	P <sub>D</sub>	MSOP8	0.58 (Note 13,16)	-	0.58 (Note 13,16)	-			
		SOP14	-	0.61 (Note 14,16)	-	0.61 (Note 14,16)			
		SSOP-B14	- 0.87 <sup>(Note 15,16)</sup>		-	0.87 (Note 15,16)			
Differential Input Voltage (Note 17)		V <sub>ID</sub>	36						
Input Common-mode Voltage Range		V <sub>ICM</sub>	(VEE-0.3) to (VEE+36)						
Input Current (Note 18)		l <sub>l</sub>	-10						
Operating Supply Voltage		$V_{opr}$	+2.0 to +36.0 (±1.0 to ±18.0)						
Operating Temperature Range		$T_{opr}$	-40 to +105 -40 to +125						
Storage Temperature Range		T <sub>stg</sub>	-55 to +150						
Maximum Junction Temperature		T <sub>jmax</sub>	+150						

<sup>(</sup>Note 11) To use at temperature above T<sub>A</sub>=25°C reduce 6.2mW.

Caution: Operating the IC over the absolute maximum ratings may damage the IC. The damage can either be a short circuit between pins or an open circuit between pins and the internal circuitry. Therefore, it is important to consider circuit protection measures, such as adding a fuse, in case the IC is operated over the absolute maximum ratings.

To use at temperature above T<sub>A</sub>=25°C reduce 4.9mW.

To use at temperature above T<sub>A</sub>=25°C reduce 7.0mW.

<sup>(</sup>Note 8) Mounted on a FR4 glass epoxy PCB(70mm×70mm×1.6mm). (Note 9) The voltage difference between inverting input and non-inverting input is the differential input voltage.

Then input terminal voltage is set to more than VEE.

<sup>(</sup>Note 10) Excessive input current will flow if a differential input voltage in excess of approximately 0.6V is applied between the input unless some limiting resistance is used.

<sup>(</sup>Note 12) To use at temperature above T<sub>A</sub>=25°C reduce 5.5mW.

<sup>(</sup>Note 13) To use at temperature above T<sub>A</sub>=25°C reduce 4.7mW.

<sup>(</sup>Note 14) To use at temperature above T<sub>A</sub>=25°C reduce 4.9mW. (Note 15) To use at temperature above T<sub>A</sub>=25°C reduce 7.0mW. (Note 16) Mounted on a FR4 glass epoxy PCB(70mm×70mm×1.6mm).

<sup>(</sup>Note 17) The voltage difference between inverting input and non-inverting input is the differential input voltage.

Then input terminal voltage is set to more than VEE.

<sup>(</sup>Note 18) Excessive input current will flow if a differential input voltage in excess of approximately 0.6V is applied between the input unless some limiting resistance is used.

#### **Electrical Characteristics**

OBA8391G(Unless otherwise specified VCC=+5V, VEE=0V, T<sub>A</sub>=25°C)

Doromotor	Symbol	Temperature I		Limit	Limit		Conditions
Parameter		Range	Min	Тур	Max	Unit	Conditions
(Note 19.20)	.,	25°C	-	2	7	.,	OUT=1.4V
Input Offset Voltage (Note 19,20)	V <sub>IO</sub>	Full range	-	-	15	mV	VCC=5 to 36V, OUT=1.4V
(Note 19.20)		25°C	-	5	50	A	OUT 4 4V
Input Offset Current (Note 19,20)	I <sub>IO</sub>	Full range	-	-	200	nA	OUT=1.4V
(Note 20.21)		25°C	-	50	250		OUT 4 AV
Input Bias Current (Note 20,21)	I <sub>B</sub>	Full range	-	-	500	nA	OUT=1.4V
Input Common-mode Voltage Range	V <sub>ICM</sub>	25°C	0	-	VCC -1.5	V	-
Laura Cianal Valtana Caia		2500	25	100	-	V/mV	VCC=15V, OUT=1.4 to 11.4V
Large Signal Voltage Gain	A <sub>V</sub>	25°C	88	100	-	dB	$R_L=15k\Omega$ , $V_{RL}=15V$
Supply Current (Note 20)	Icc	25°C	-	0.3	0.7	Λ	OUT=Open
Supply Current		Full range	-	-	1.3	mA	OUT=Open, VCC=36V
Output Sink Current <sup>(Note 22)</sup>	I <sub>SINK</sub>	25°C	6	16	-	mA	+IN=0V, -IN=1V OUT=1.5V
Output Saturation Voltage (Note 20)		25°C	-	150	400	>/	+IN= 0V, -IN=1V
(Low Level Output Voltage)	V <sub>OL</sub>	Full range	-	-	700	mV	I <sub>SINK</sub> =4mA
Output Leakage Current (Note 20)		25°C	-	0.1	-	nA	+IN=1V, -IN=0V OUT=5V
(High Level Output Current)	I <sub>LEAK</sub>	Full range	-	-	1	μА	+IN=1V, -IN=0V OUT=36V
D T		0500	-	1.3	-		$R_L$ =5.1k $\Omega$ , $V_{RL}$ =5V IN=100m $V_{P-P}$ , Overdrive=5mV
Response Time	t <sub>RE</sub>	25°C	-	0.4	-	μs	$R_L$ =5.1k $\Omega$ , $V_{RL}$ =5V, IN=TTL Logic Swing, $V_{REF}$ =1.4V

<sup>(</sup>Note 19) Absolute value

<sup>(</sup>Note 20) Full range T<sub>A</sub>=-40°C to +85°C

<sup>(</sup>Note 21) Current Direction: Because the first stage is composed with PNP transistor, input bias current flows out of IC.

<sup>(</sup>Note 22) Please determine the output current value in consideration of the power dissipation of the IC under high temperature environment. When the output terminal is continuously shorted, output current may be reduced by the temperature rise of the IC.

OBA10393F (Unless otherwise specified VCC=+5V, VEE=0V, TA=25°C)

Parameter	Symbol	Temperature		Limit		Unit	Conditions
	Symbol	Range	Min	Тур	Max	Unit	Conditions
Input Offset Voltage (Note 23)	V <sub>IO</sub>	25°C	-	1	5	mV	OUT=1.4V
Input Offset Current (Note 23)	I <sub>IO</sub>	25°C	-	5	50	nA	OUT=1.4V
Input Bias Current (Note 24)	lΒ	25°C	-	50	250	nA	OUT=1.4V
Input Common-mode Voltage Range	V <sub>ICM</sub>	25°C	0	-	VCC -1.5	V	-
Large Signal Voltage Cain	^	25°C	50	200	-	V/mV	VCC=15V, OUT=1.4 ~ 11.4V
Large Signal Voltage Gain	A <sub>V</sub>	25 C	94	106	-	dB	$R_L$ =15 $k\Omega$ , $V_{RL}$ =15 $V$
Supply Current	Icc	25°C	-	0.4	1	mA	R <sub>L</sub> =∞, All Comparators
Output Sink Current (Note 25)	I <sub>SINK</sub>	25°C	6	16	-	mA	-IN=1V, +IN=0V OUT=1.5V
Output Saturation Voltage (Low Level Output Voltage)	V <sub>OL</sub>	25°C	-	250	400	mV	-IN=1V, +IN=0V I <sub>SINK</sub> =4mA
Output Leakage Current		25°C	-	0.1	-	nA	-IN=0V, +IN=1V OUT=5V
(High Level Output Current)	I <sub>LEAK</sub>	25°C	-	-	1	μA	-IN=0V, +IN=1V OUT=36V
Response Time	t	25°C	-	1.3	-	. IIC	$R_L$ =5.1k $\Omega$ , $V_{RL}$ =5V IN=100m $V_{P-P}$ , Overdrive=5mV
	t <sub>RE</sub>		-	0.4	-	μs	$R_L$ =5.1k $\Omega$ , $V_{RL}$ =5V, IN=TTL Logic Swing, $V_{REF}$ =1.4V

<sup>(</sup>Note 23) Absolute value

#### OBA10339 xx(Unless otherwise specified VCC=+5V, VEE=0V, TA=25°C)

Devementer	Comple	Temperature		Limit		l lm:4	Conditions
Parameter	Symbol	Range	Min	Тур	Max	Unit	Conditions
Input Offset Voltage (Note 26)	V <sub>IO</sub>	25°C	-	1	5	mV	OUT=1.4V
Input Offset Current (Note 26)	I <sub>IO</sub>	25°C	-	5	50	nA	OUT=1.4V
Input Bias Current (Note 27)	IΒ	25°C	-	50	250	nA	OUT=1.4V
Input Common-mode Voltage Range	V <sub>ICM</sub>	25°C	0	-	VCC -1.5	V	-
Large Signal Voltage Cain	^	2500	50	200	-	V/mV	VCC=15V, OUT=1.4 ~ 11.4V
Large Signal Voltage Gain	$A_{V}$	25°C	94	106	-	dB	$R_L$ =15 $k\Omega$ , $V_{RL}$ =15 $V$
Supply Current	Icc	25°C	-	0.8	2	mA	R <sub>L</sub> =∞, All Comparators
Output Sink Current <sup>(Note 28)</sup>	I <sub>SINK</sub>	25°C	6	16	-	mA	-IN=1V, +IN=0V OUT=1.5V
Output Saturation Voltage (Low Level Output Voltage)	V <sub>OL</sub>	25°C	-	250	400	mV	-IN=1V, +IN=0V I <sub>SINK</sub> =4mA
Output Leakage Current		25°C	-	0.1	-	nA	-IN=0V, +IN=1V OUT=5V
(High Level Output Current)	ILEAK	25°C	-	-	1	μA	-IN=0V, +IN=1V OUT=36V
Doopooo Timo		25°C	-	1.3	-		$R_L$ =5.1k $\Omega$ , $V_{RL}$ =5V IN=100m $V_{P-P}$ , Overdrive=5mV
Response Time	t <sub>RE</sub>		1	0.4		μs	$R_L$ =5.1k $\Omega$ , $V_{RL}$ =5V, IN=TTL Logic Swing, $V_{REF}$ =1.4V

<sup>(</sup>Note 26) Absolute value

<sup>(</sup>Note 24) Current Direction: Because the first stage is composed with PNP transistor, input bias current flows out of IC.

<sup>(</sup>Note 25) Please determine the output current value in consideration of the power dissipation of the IC under high temperature environment. When the output terminal is continuously shorted, output current may be reduced by the temperature rise of the IC.

<sup>(</sup>Note 27) Current Direction: Because the first stage is composed with PNP transistor, input bias current flows out of IC.

<sup>(</sup>Note 28) Please determine the output current value in consideration of the power dissipation of the IC under high temperature environment. When the output terminal is continuously shorted, output current may be reduced by the temperature rise of the IC.

OBA2903xxx, BA2903S xxx(Unless otherwise specified VCC=+5V, VEE=0V, TA=25°C)

Developed	Coursels al	Temperature Limit		l lait	Conditions			
Parameter	Symbol	Range	Min	Тур	Max	Unit	Conditions	
(Note 29,30)		25°C	-	2	7	>/	OUT=1.4V	
Input Offset Voltage (Note 29,30)	V <sub>IO</sub>	Full range	-	-	15	mV	VCC=5 to 36V, OUT=1.4V	
Input Offset Current (Note 29,30)		25°C	-	5	50	Λ	OUT=1.4V	
input Offset Current	I <sub>IO</sub>	Full range	-	-	200	nA	001=1.40	
Input Bias Current (Note 30,31)		25°C	-	50	250	^	OUT 4 4V	
input Bias Current	I <sub>B</sub>	Full range	-	-	500	nA	OUT=1.4V	
Input Common-mode Voltage Range	V <sub>ICM</sub>	25°C	0	-	VCC -1.5	V	-	
Lorgo Signal Voltago Cain	_	2500	25	100	-	V/mV	VCC=15V, OUT=1.4 to 11.4V	
Large Signal Voltage Gain	A <sub>V</sub>	25°C	88	100	-	dB	$R_L=15k\Omega$ , $V_{RL}=15V$	
Supply Current (Note 30)	Icc	25°C	-	0.6	1	A	OUT=Open	
Supply Current		Full range	-	-	2.5	mA	OUT=Open, VCC=36V	
Output Sink Current <sup>(Note 32)</sup>	I <sub>SINK</sub>	25°C	6	16	-	mA	+IN=0V, -IN=1V OUT=1.5V	
Output Saturation Voltage <sup>(Note 30)</sup>		25°C	-	150	400	\/	+IN=0V, -IN= 1V	
(Low Level Output Voltage)	V <sub>OL</sub>	Full range	-	-	700	mV	I <sub>SINK</sub> =4mA	
Output Leakage Current (Note 30)		25°C	-	0.1	-	nA	+IN=1V, -IN=0V OUT=5V	
(High Level Output Current)	I <sub>LEAK</sub>	Full range	-	-	1	μA	+IN=1V, -IN=0V OUT=36V	
Dannes Time	_	2500	-	1.3	-		R <sub>L</sub> =5.1kΩ, V <sub>RL</sub> =5V IN=100mV <sub>P-P</sub> , Overdrive=5mV	
Response Time	t <sub>RE</sub>	25°C	-	0.4	-	μs	R <sub>L</sub> =5.1kΩ, V <sub>RL</sub> =5V, IN=TTL Logic Swing, V <sub>REF</sub> =1.4V	

<sup>(</sup>Note 29) Absolute value

<sup>(</sup>Note 30) BA2903S : Full range -40°C to +105°C, BA2903: Full range -40°C to +125°C

<sup>(</sup>Note 31) Current Direction: Because the first stage is composed with PNP transistor, input bias current flows out of IC.

<sup>(</sup>Note 32) Please determine the output current value in consideration of the power dissipation of the IC under high temperature environment. When the output terminal is continuously shorted, output current may be reduced by the temperature rise of the IC.

OBA2903Wxx (Unless otherwise specified VCC=+5V, VEE=0V, T<sub>A</sub>=25°C)

Parameter	Symbol	Temperature	Limit			l lmit	Conditions
		Range	Min	Тур	Max	Unit	Conditions
Input Offset Voltage (Note 33)	V <sub>IO</sub>	25°C	-	0.5	2	mV	OUT=1.4V
Input Offset Current (Note 33)	I <sub>IO</sub>	25°C	-	5	50	nA	OUT=1.4V
Input Bias Current (Note 34,35)	I <sub>B</sub>	25°C	-	50	250	nA	OUT=1.4V
		Full range	-	-	500		
Input Common-mode Voltage Range	V <sub>ICM</sub>	25°C	0	-	VCC -1.5	V	-
Large Signal Voltage Gain	Av	25°C	25	100	-	V/mV	VCC=15V, OUT=1.4 to 11.4V $R_L$ =15kΩ, $V_{RL}$ =15V
			88	100	-	dB	
Supply Current (Note 34)	Icc	25°C	-	0.6	1	mA	OUT=Open
		Full range	-	-	2.5		OUT=Open, VCC=36V
Output Sink Current (Note 36)	I <sub>SINK</sub>	25°C	6	16	-	mA	+IN=0V, -IN=1V OUT=1.5V
Output Saturation Voltage <sup>(Note 34)</sup> (Low Level Output Voltage)	V <sub>OL</sub>	25°C	-	150	400	mV	+IN=0V, -IN= 1V I <sub>SINK</sub> =4mA
		Full range	-	-	700		
Output Leakage Current (Note 34) (High Level Output Current)	I <sub>LEAK</sub>	25°C	-	0.1	-	nA	+IN=1V, -IN=0V OUT=5V
		Full range	-	-	1	μA	+IN=1V, -IN=0V OUT=36V
Response Time	t <sub>RE</sub>	25°C	-	1.3	-	μs	$R_L$ =5.1k $\Omega$ , $V_{RL}$ =5V IN=100m $V_{P-P}$ , Overdrive=5mV
			-	0.4	-		$R_L$ =5.1k $\Omega$ , $V_{RL}$ =5V, IN=TTL Logic Swing, $V_{REF}$ =1.4V

<sup>(</sup>Note 33) Absolute value

<sup>(</sup>Note 34) BA2903W: Full range -40°C to +125°C

<sup>(</sup>Note 35) Current Direction: Because the first stage is composed with PNP transistor, input bias current flows out of IC.

<sup>(</sup>Note 36) Please determine the output current value in consideration of the power dissipation of the IC under high temperature environment. When the output terminal is continuously shorted, output current may be reduced by the temperature rise of the IC.

OBA2901xx, BA2901S xx(Unless otherwise specified VCC=+5V, VEE=0V, Ta=25°C)

Parameter	Symbol	Temperature Range	Limit			Linit	Conditions
			Min	Тур	Max	Unit	Conditions
Input Offset Voltage (Note 37,38)	V <sub>IO</sub>	25°C	-	2	7	mV	OUT=1.4V
		Full range	-	-	15		VCC=5 to 36V, OUT=1.4V
Input Offset Current (Note 37,38)	I <sub>IO</sub>	25°C	-	5	50	nA	OUT=1.4V
		Full range	-	-	200		
Input Bias Current (Note 38,39)	I <sub>B</sub>	25°C	-	50	250	nA	OUT=1.4V
		Full range	-	-	500		
Input Common-mode Voltage Range	V <sub>ICM</sub>	25°C	0	-	VCC-1.5	٧	-
Large Signal Voltage Gain	A <sub>V</sub>	25°C	25	100	-	V/mV dB	VCC=15V, OUT=1.4 to 11.4V $R_L$ =15k $\Omega$ , $V_{RL}$ =15V
			88	100	-		
Supply Current (Note 38)	Icc	25°C	-	0.8	2	mA	OUT=Open
		Full range	-	-	2.5		OUT=Open, VCC=36V
Output Sink Current <sup>(Note 40)</sup>	I <sub>SINK</sub>	25°C	6	16	-	mA	+IN=0V, V <sub>IN</sub> =1V OUT=1.5V
Output Saturation Voltage <sup>(Note 38)</sup> (Low Level Output Voltage)	V <sub>OL</sub>	25°C	-	150	400	mV	+IN=0V, -IN=1V I <sub>SINK</sub> =4mA
		Full range	-	-	700		
Output Leakage Current (Note 38) (High Level Output Current)	I <sub>LEAK</sub>	25°C	-	0.1	-	nA	+IN=1V, -IN=0V OUT=5V
		Full range	-	-	1	μA	+IN=1V, -IN=0V OUT=36V
Response Time	t <sub>RE</sub>	25°C	-	1.3	-	μs	$R_L$ =5.1k $\Omega$ , $V_{RL}$ =5V $V_{IN}$ =100m $V_{P-P}$ , Overdrive=5mV
			-	0.4	-		$R_L$ =5.1k $\Omega$ , $V_{RL}$ =5V, $V_{IN}$ =TTL Logic Swing, $V_{REF}$ =1.4V

<sup>(</sup>Note 37) Absolute value

<sup>(</sup>Note 38) BA2901S : Full range -40°C to 105°C ,BA2901 : Full range -40°C to +125°C

<sup>(</sup>Note 39) Current Direction: Because the first stage is composed with PNP transistor, input bias current flows out of IC.

<sup>(</sup>Note 40) Please determine the output current value in consideration of the power dissipation of the IC under high temperature environment. When the output terminal is continuously shorted, output current may be reduced by the temperature rise of the IC.

#### **Description of electrical characteristics**

Described below are descriptions of the relevant electrical terms used in this datasheet. Items and symbols used are also shown. Note that item name and symbol and their meaning may differ from those on another manufacturer's document or general document.

#### 1. Absolute maximum ratings

Absolute maximum rating items indicate the condition which must not be exceeded. Application of voltage in excess of absolute maximum rating or use out of absolute maximum rated temperature environment may cause deterioration of characteristics.

- (1) Power supply voltage (VCC/VEE)
  - Indicates the maximum voltage that can be applied between the positive power supply terminal and negative power supply terminal without deterioration or destruction of characteristics of internal circuit.
- (2) Differential input voltage (V<sub>ID</sub>)
  Indicates the maximum voltage that can be applied between non-inverting and inverting terminals without damaging
- (3) Input common-mode voltage range (V<sub>ICM</sub>)

Indicates the maximum voltage that can be applied to the non-inverting and inverting terminals without deterioration or destruction of electrical characteristics. Input common-mode voltage range of the maximum ratings does not assure normal operation of IC. For normal operation, use the IC within the input common-mode voltage range characteristics.

(4) Power dissipation (Pd)

Indicates the power that can be consumed by the IC when mounted on a specific board at the ambient temperature 25°C (normal temperature). As for package product, Pd is determined by the temperature that can be permitted by the IC in the package (maximum junction temperature) and the thermal resistance of the package.

#### 2. Electrical characteristics

- (1) Input offset voltage (V<sub>IO</sub>)
  - Indicates the voltage difference between non-inverting terminal and inverting terminals. It can be translated into the input voltage difference required for setting the output voltage at 0 V.
- (2) Input offset current (I<sub>IO</sub>)
  - Indicates the difference of input bias current between the non-inverting and inverting terminals.
- (3) Input bias current (IB)
  - Indicates the current that flows into or out of the input terminal. It is defined by the average of input bias currents at the non-inverting and inverting terminals.
- (4) Input common-mode voltage range  $(V_{ICM})$ 
  - Indicates the input voltage range where IC normally operates.
- (5) Large signal voltage gain (A<sub>V</sub>)

Indicates the amplifying rate (gain) of output voltage against the voltage difference between non-inverting terminal and inverting terminal. It is normally the amplifying rate (gain) with reference to DC voltage.

- Av = (Output voltage) / (Differential Input voltage)
- (6) Supply current (I<sub>CC</sub>)
  - Indicates the current that flows within the IC under specified no-load conditions.
- (7) Output sink current (I<sub>SINK</sub>)
  - Denotes the maximum current that can be output under specific output conditions.
- (8) Output saturation voltage, low level output voltage (V<sub>OL</sub>)
  - Signifies the voltage range that can be output under specific output conditions.
- (9) Output leakage current, High level output current (ILEAK)
  - Indicates the current that flows into the IC under specific input and output conditions.
- (10) Response time (t<sub>RE</sub>)
  - Response time indicates the delay time between the input and output signal is determined by the time difference from the fifty percent of input signal swing to the fifty percent of output signal swing.

## **Typical Performance Curves**

OBA8391G

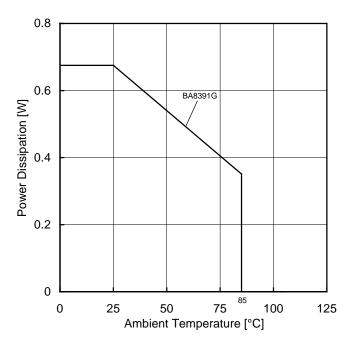


Figure 2.
Power Dissipation vs Ambient Temperature
(Derating Curve)

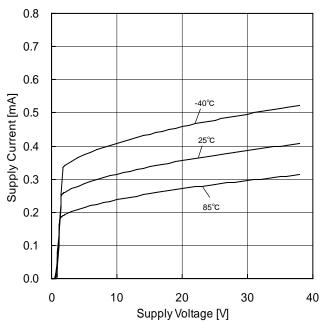


Figure 3. Supply Current vs Supply Voltage

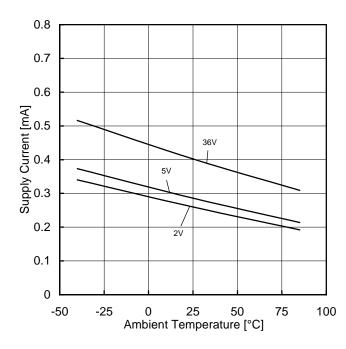


Figure 4.
Supply Current vs Ambient Temperature

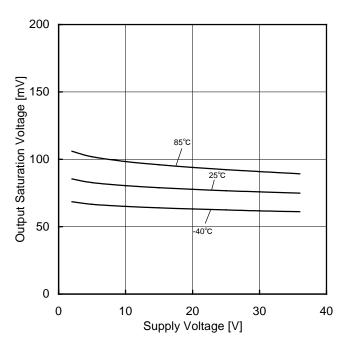


Figure 5.
Output Saturation Voltage vs Supply Voltage
(I<sub>OL</sub>=4mA)

OBA8391G

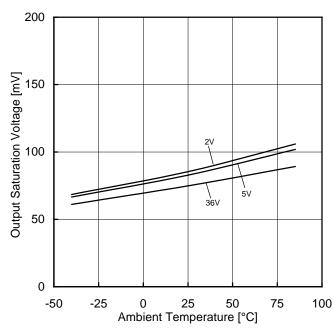


Figure 6. Output Saturation Voltage vs Ambient Temperature (  $I_{OL}$ =4mA)

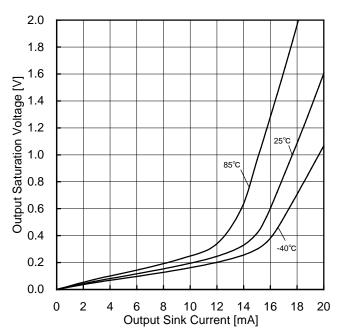


Figure 7.
Output Saturation Voltage vs
Output Sink Current
(VCC=5V)

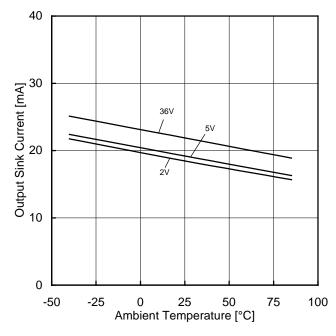


Figure 8.
Output Sink Current vs Ambient Temperature
(OUT=1.5V)

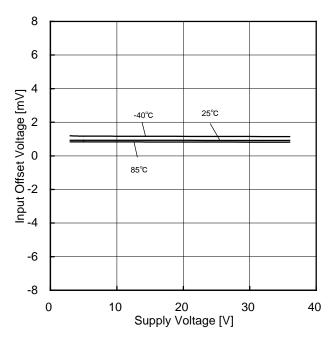
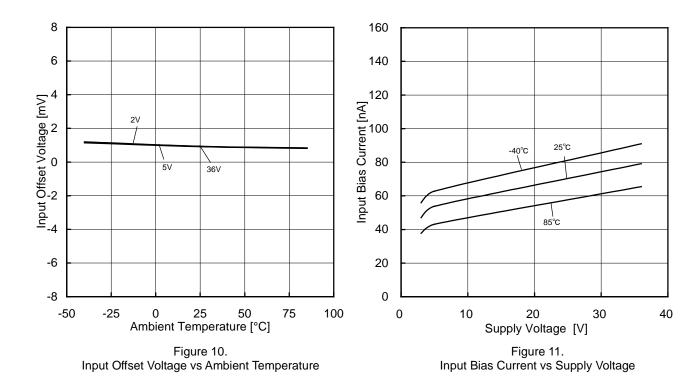
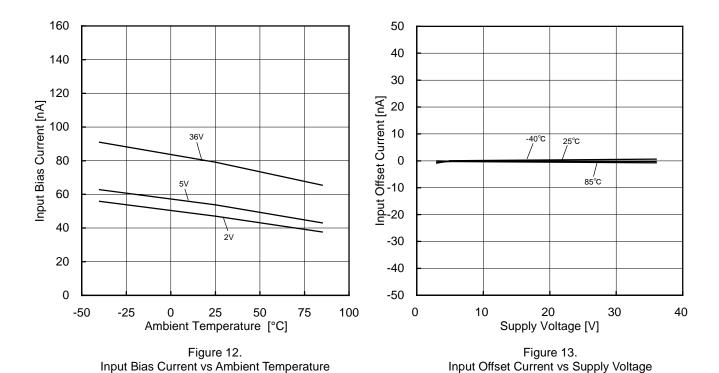


Figure 9. Input Offset Voltage vs Supply Voltage

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OBA8391G

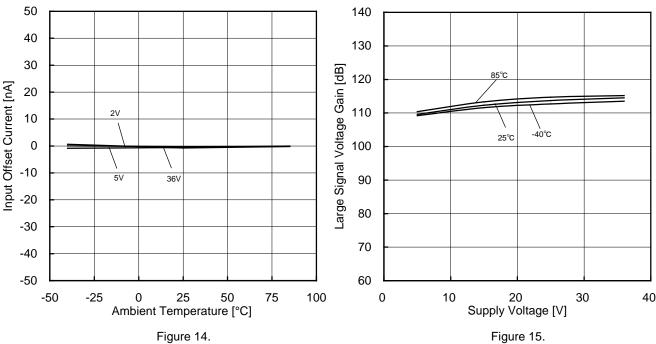
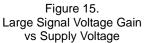
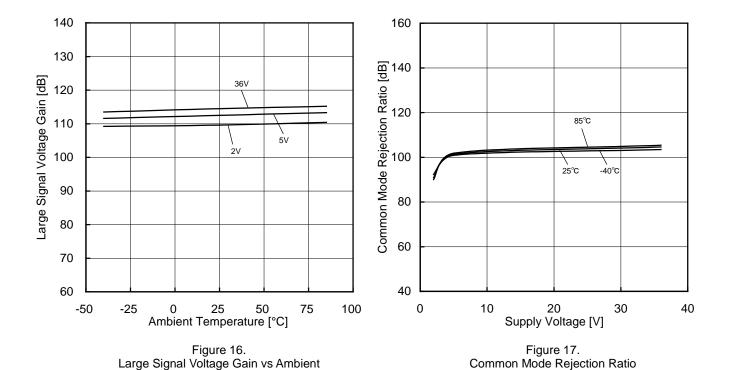


Figure 14.
Input Offset Current vs Ambient Temperature





(\*)The above characteristics are measurements of typical sample, they are not guaranteed.

Temperature

vs Supply Voltage

OBA8391G

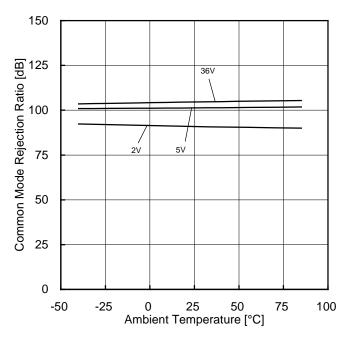


Figure 18.
Common Mode Rejection Ratio vs Ambient
Temperature

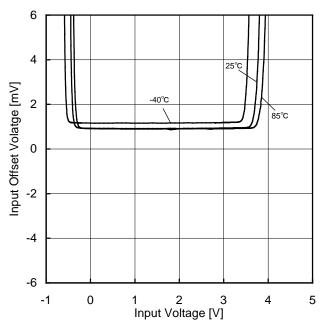


Figure 19.
Input Offset Voltage - Input Voltage
(VCC=5V)

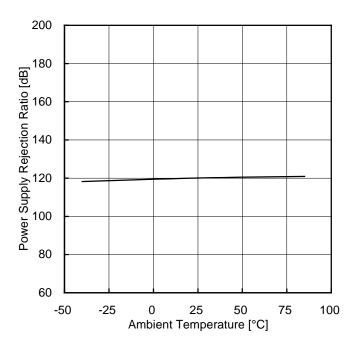


Figure 20.
Power Supply Rejection Ratio vs Ambient
Temperature

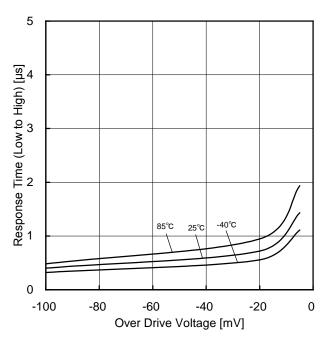


Figure 21.
Response Time (Low to High)
vs Over Drive Voltage
(VCC=5V, V<sub>RL</sub>=5V, R<sub>L</sub>=5.1kΩ)

OBA8391G

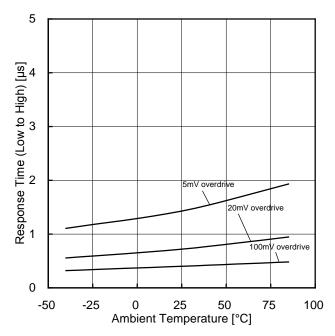


Figure 22.
Response Time (Low to High)
vs Ambient Temperature
(VCC=5V, V<sub>RL</sub>=5V, R<sub>L</sub>=5.1kΩ)

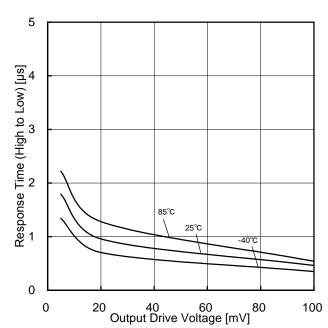


Figure 23.
Response Time (High to Low)
vs Over Drive Voltage
(VCC=5V, V<sub>RL</sub>=5V, R<sub>L</sub>=5.1kΩ)

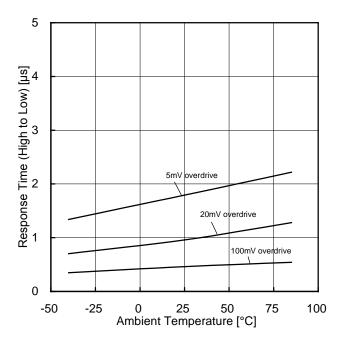


Figure 24. Response Time (High to Low) vs Ambient Temperature (VCC=5V,  $V_{RL}$ =5V,  $R_L$ =5.1k $\Omega$ )

**OBA10393F** 

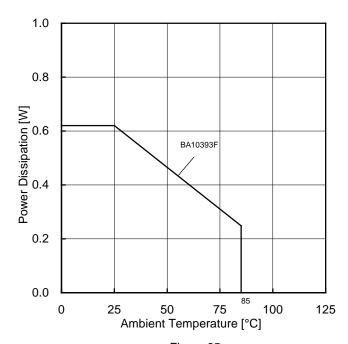


Figure 25.
Power Dissipation vs Ambient Temperature (Derating Curve)

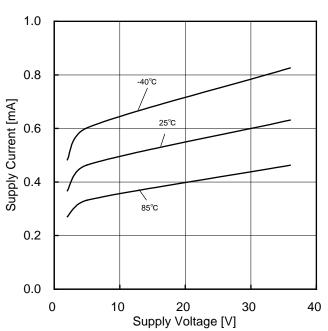


Figure 26. Supply Current vs Supply Voltage

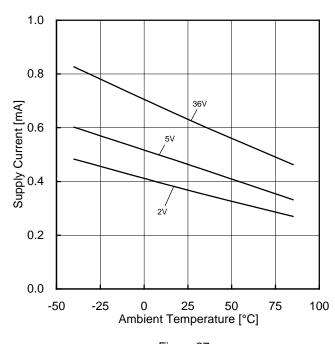


Figure 27.
Supply Current vs Ambient Temperature

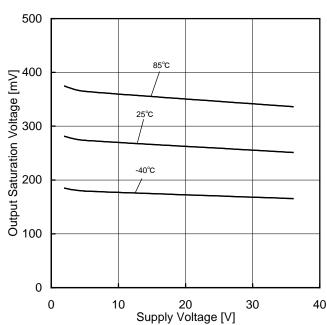


Figure 28. Output Saturation Voltage vs Supply Voltage  $(I_{OL}=4mA)$ 

**OBA10393F** 

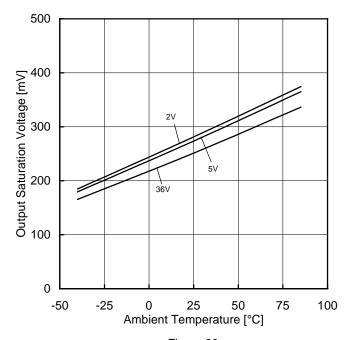


Figure 29.

Output Saturation Voltage vs Ambient Temperature ( $I_{OL}$ =4mA)

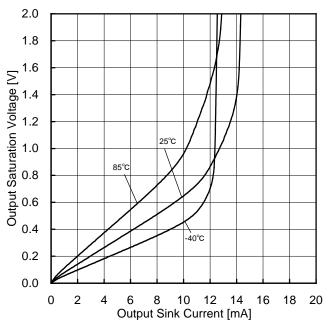


Figure 30.
Output Saturation Voltage vs
Output Sink Current
(VCC=5V)

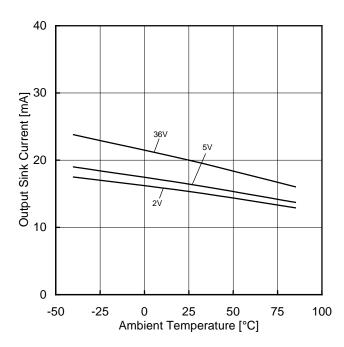


Figure 31.
Output Sink Current vs Ambient Temperature
(OUT=1.5V)

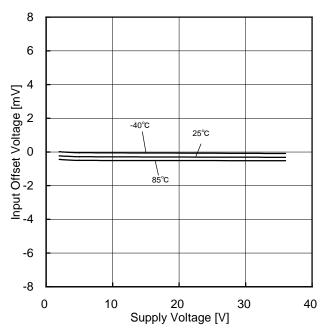
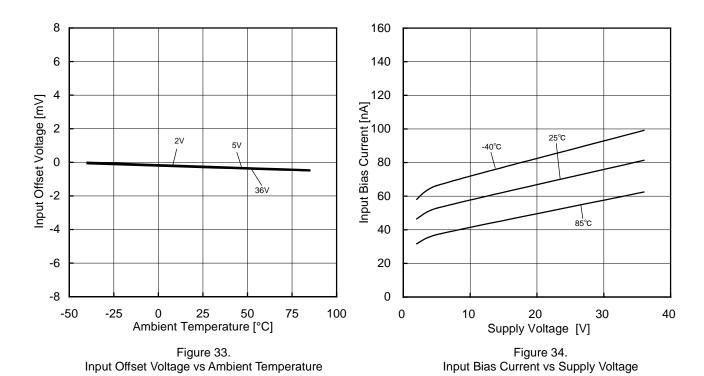
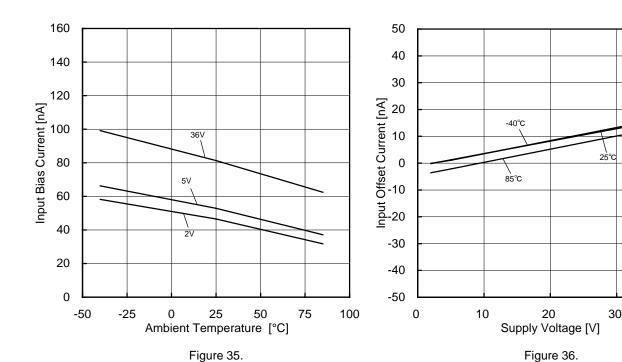


Figure 32. Input Offset Voltage vs Supply Voltage

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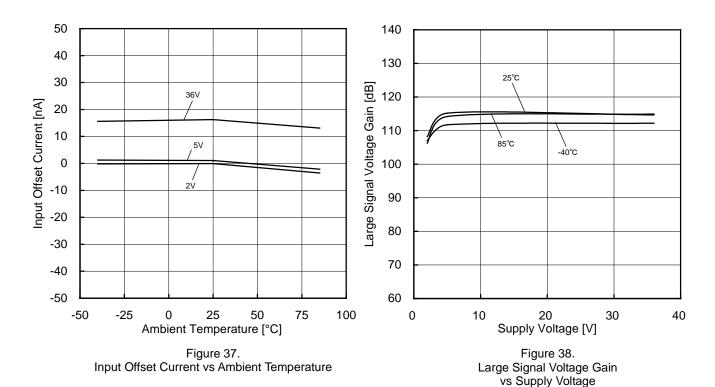
(\*)The above characteristics are measurements of typical sample, they are not guaranteed.

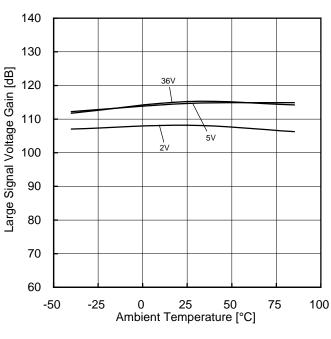
Input Bias Current vs Ambient Temperature

Input Offset Current vs Supply Voltage

40

**OBA10393F** 





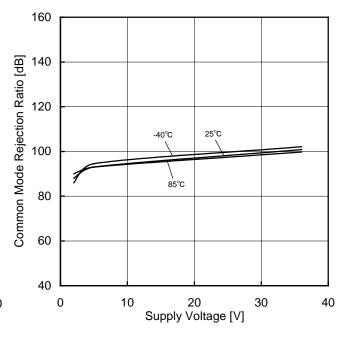


Figure 39. Large Signal Voltage Gain vs Ambient Temperature

Figure 40. Common Mode Rejection Ratio vs Supply Voltage

**OBA10393F** 

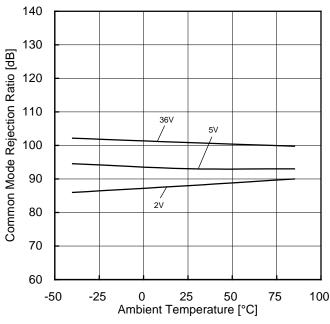


Figure 41.
Common Mode Rejection Ratio vs Ambient
Temperature

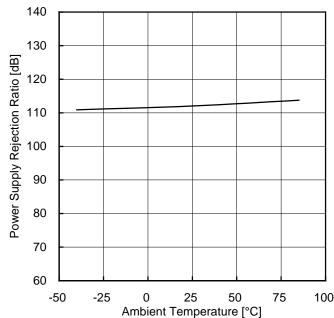


Figure 42.
Power Supply Rejection Ratio vs Ambient
Temperature

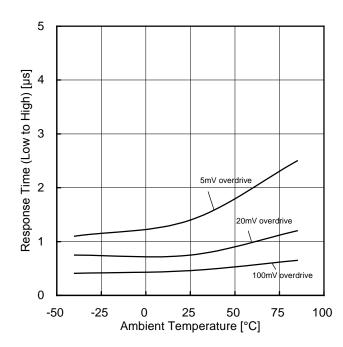


Figure 43. Response Time (Low to High) vs Ambient Temperature (VCC=5V,  $V_{RL}$ =5V,  $R_L$ =5.1k $\Omega$ )

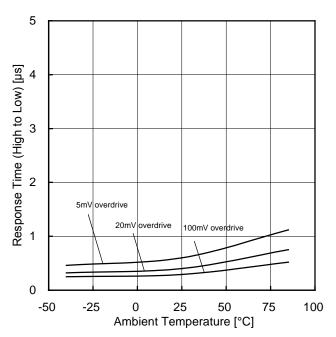


Figure 44. Response Time (High to Low) vs Ambient Temperature (VCC=5V,  $V_{RL}$ =5V,  $R_L$ =5.1k $\Omega$ )

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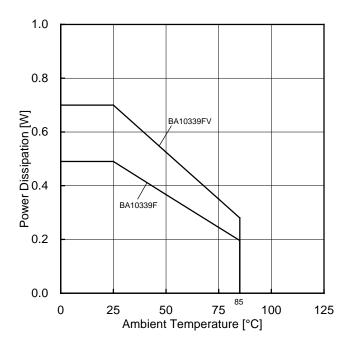


Figure 45.
Power Dissipation vs Ambient Temperature
(Derating Curve)

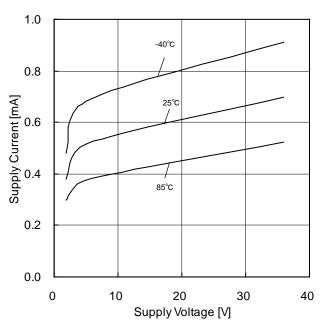


Figure 46.
Supply Current vs Supply Voltage

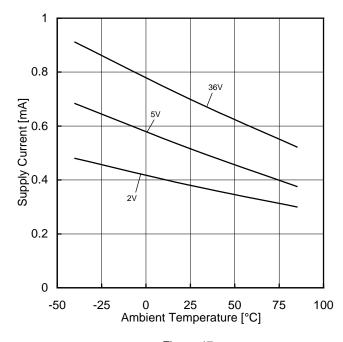


Figure 47.
Supply Current vs Ambient Temperature

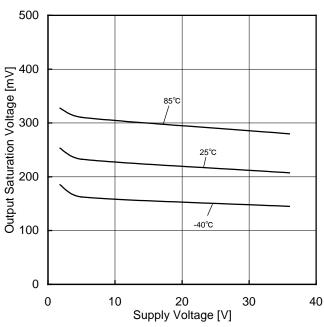


Figure 48.

Output Saturation Voltage vs Supply Voltage  $(I_{OL}=4mA)$ 

OBA10339xx

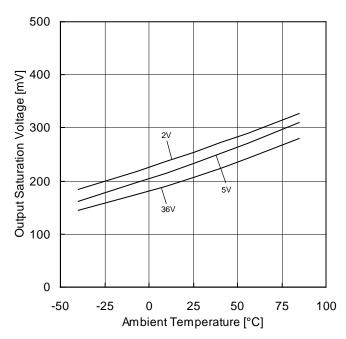


Figure 49.

Output Saturation Voltage vs Ambient Temperature ( $I_{OL}$ =4mA)

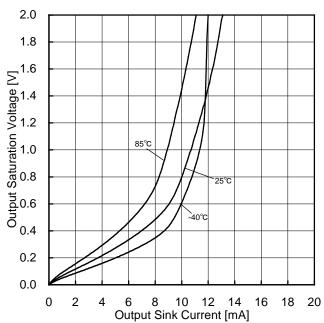


Figure 50.
Output Saturation Voltage vs
Output Sink Current
(VCC=5V)

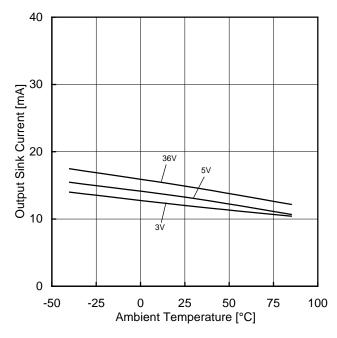


Figure 51.
Output Sink Current vs Ambient Temperature
(OUT=1.5V)

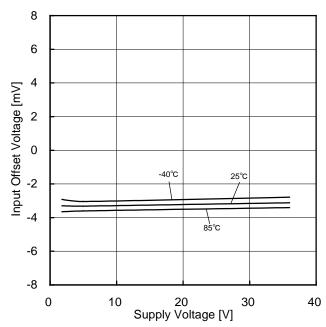


Figure 52. Input Offset Voltage vs Supply Voltage

OBA10339xx

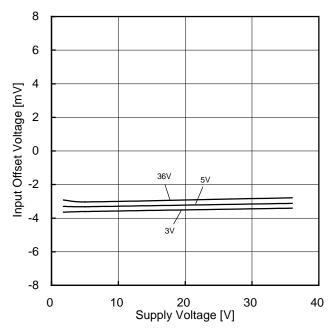


Figure 53.
Input Offset Voltage vs Ambient Temperature

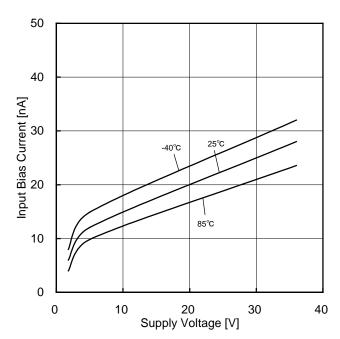


Figure 54.
Input Bias Current vs Supply Voltage

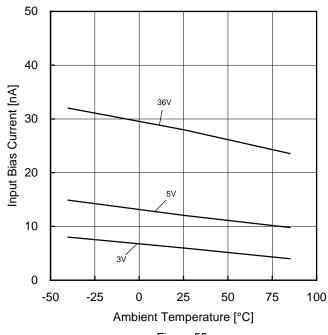


Figure 55.
Input Bias Current vs Ambient Temperature

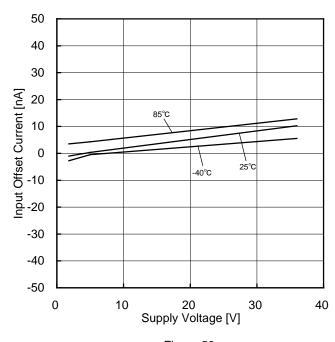
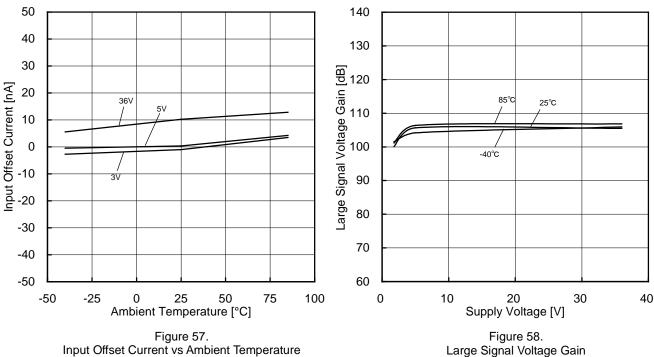
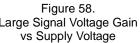
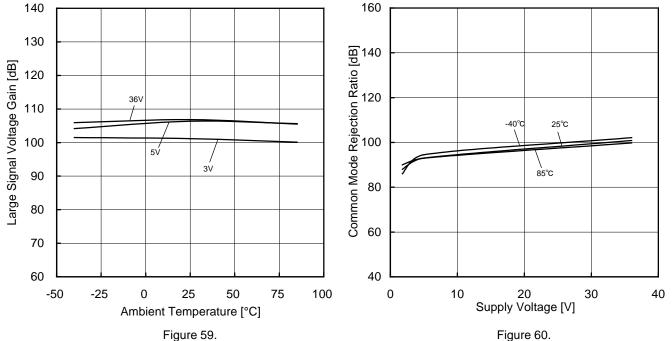


Figure 56.
Input Offset Current vs Supply Voltage

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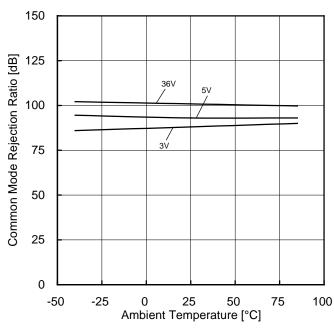


Temperature

Large Signal Voltage Gain vs Ambient

Common Mode Rejection Ratio vs Supply Voltage

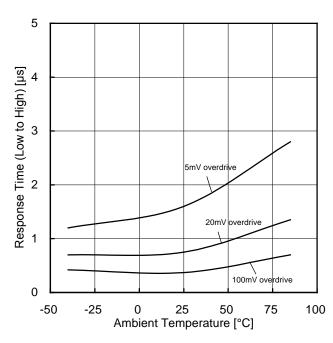
OBA10339xx



140 130 Power Supply Rejection Ratio [dB] 120 110 100 90 80 70 60 -50 -25 0 25 50 75 100 Ambient Temperature [°C]

Figure 61. Common Mode Rejection Ratio vs Ambient Temperature

Figure 62.
Power Supply Rejection Ratio vs Ambient
Temperature



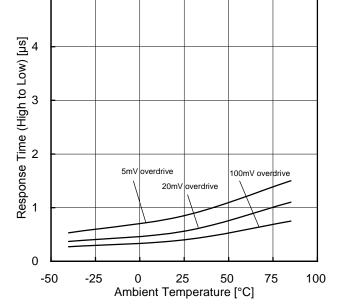


Figure 63. Response Time (Low to High) vs Ambient Temperature (VCC=5V,  $V_{RL}$ =5V,  $R_L$ =5.1k $\Omega$ )

Figure 64. Response Time (High to Low) vs Ambient Temperature (VCC=5V,  $V_{RL}$ =5V,  $R_L$ =5.1k $\Omega$ )

(\*)The above characteristics are measurements of typical sample, they are not guaranteed.

5

OBA2903xxx, BA2903Sxxx, BA2903Wxx

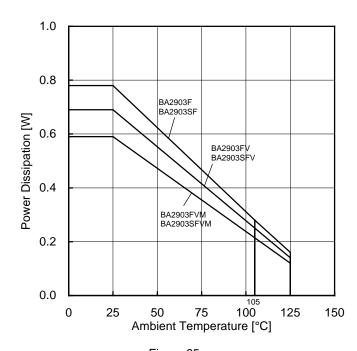


Figure 65.
Power Dissipation vs Ambient Temperature (Derating Curve)
(Refer to the following operating temperature)

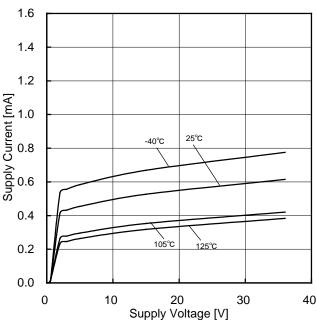


Figure 66. Supply Current vs Supply Voltage

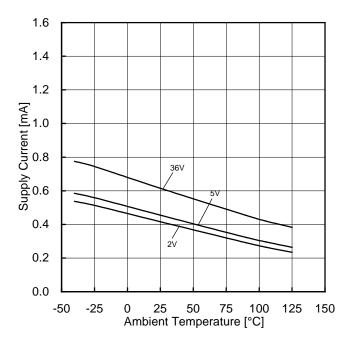


Figure 67.
Supply Current vs Ambient Temperature

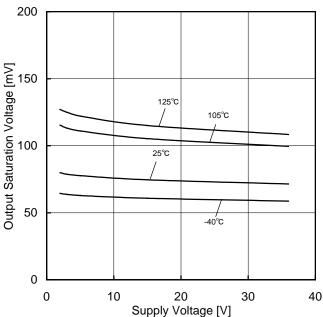


Figure 68.

Output Saturation Voltage vs Supply Voltage  $(I_{OL}=4mA)$ 

(\*)The above characteristics are measurements of typical sample, they are not guaranteed.

BA2903: -40°C to +125°C BA2903S: -40°C to +105°C BA2903W: -40°C to +125°C

OBA2903xxx, BA2903Sxxx, BA2903Wxx

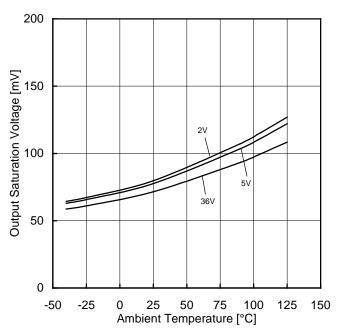


Figure 69. Output Saturation Voltage vs Ambient Temperature (  $I_{OL}$ =4mA)

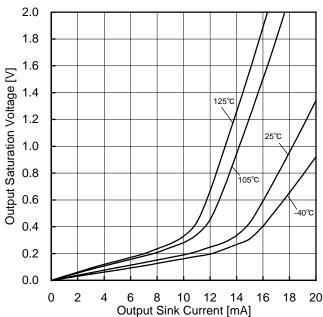


Figure 70.
Output Saturation Voltage vs
Output Sink Current
(VCC=5V)

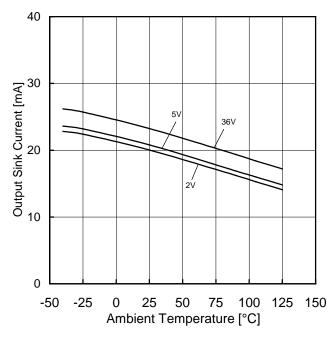


Figure 71.
Output Sink Current vs Ambient Temperature
(OUT=1.5V)

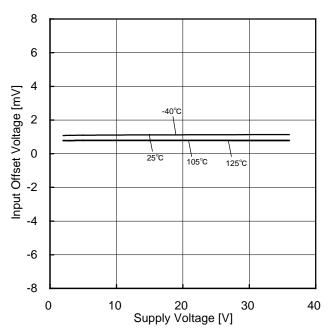
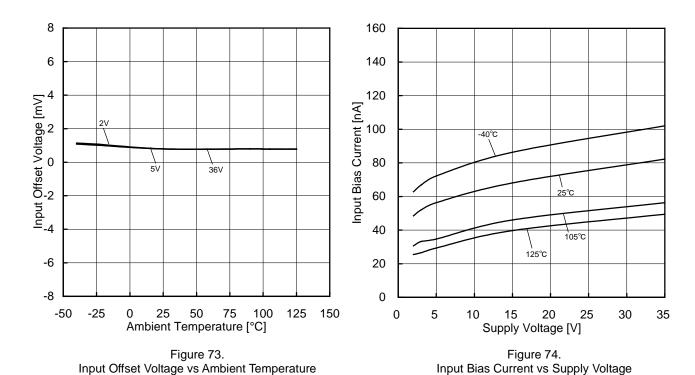


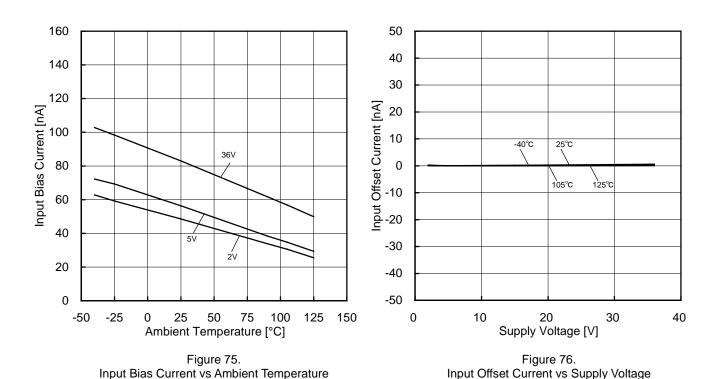
Figure 72. Input Offset Voltage vs Supply Voltage

(\*)The above characteristics are measurements of typical sample, they are not guaranteed.

BA2903: -40°C to +125°C BA2903S: -40°C to +105°C BA2903W: -40°C to +125°C

OBA2903xxx, BA2903Sxxx, BA2903Wxx





(\*)The above characteristics are measurements of typical sample, they are not guaranteed.

BA2903: -40°C to +125°C BA2903S: -40°C to +105°C BA2903W: -40°C to +125°C

30/53

OBA2903xxx, BA2903Sxxx, BA2903Wxx

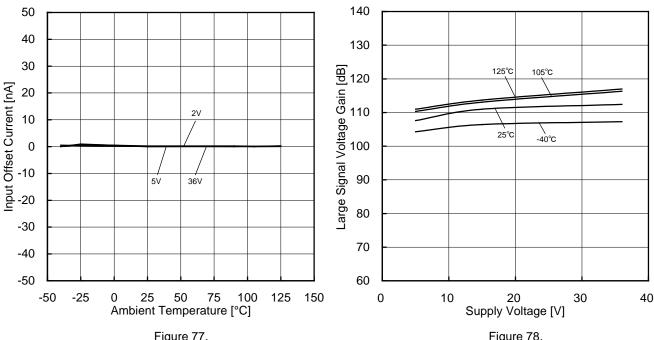
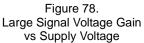
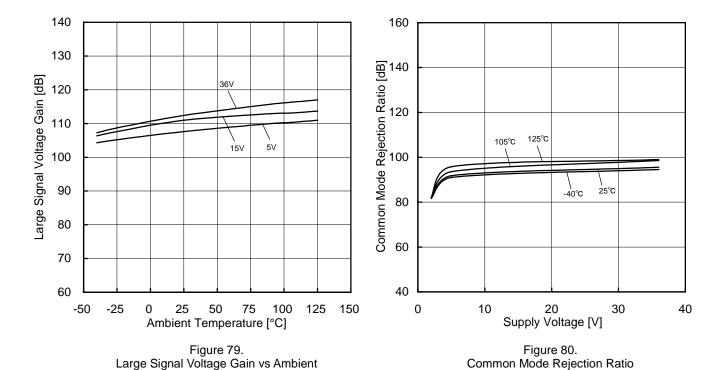


Figure 77.
Input Offset Current vs Ambient Temperature





(\*)The above characteristics are measurements of typical sample, they are not guaranteed. BA2903 : -40°C to  $\pm$ 125°C BA2903S : -40°C to  $\pm$ 105°C BA2903W : -40°C to  $\pm$ 125°C

Temperature

vs Supply Voltage

OBA2903xxx, BA2903Sxxx, BA2903Wxx

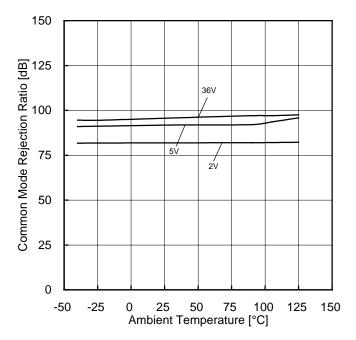


Figure 81.
Common Mode Rejection Ratio vs Ambient
Temperature

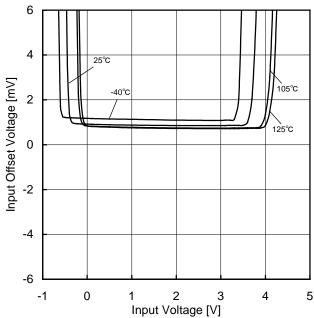


Figure 82.
Input Offset Voltage - Input Voltage (VCC=5V)

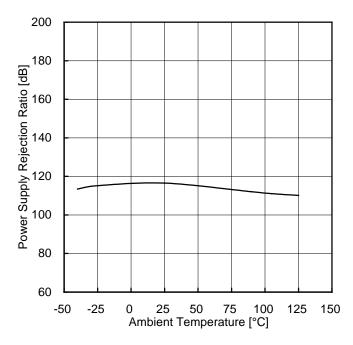


Figure 83.
Power Supply Rejection Ratio vs Ambient
Temperature

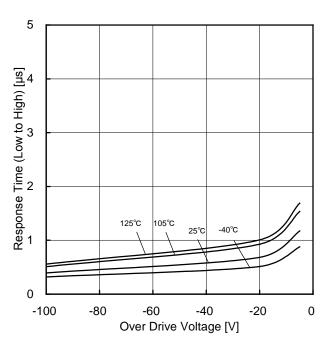


Figure 84. Response Time (Low to High) vs Over Drive Voltage (VCC=5V,  $V_{RL}$ =5V,  $R_L$ =5.1k $\Omega$ )

(\*)The above characteristics are measurements of typical sample, they are not guaranteed. BA2903 : -40°C to +125°C BA2903S : -40°C to +105°C BA2903W : -40°C to +125°C

OBA2903xxx, BA2903Sxxx, BA2903Wxx

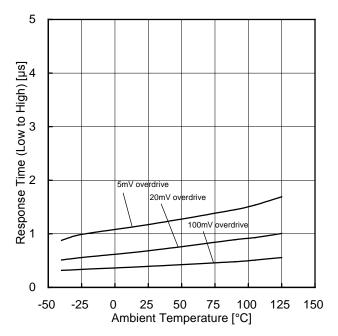


Figure 85.
Response Time (Low to High)
vs Ambient Temperature
(VCC=5V, V<sub>RL</sub>=5V, R<sub>L</sub>=5.1kΩ)

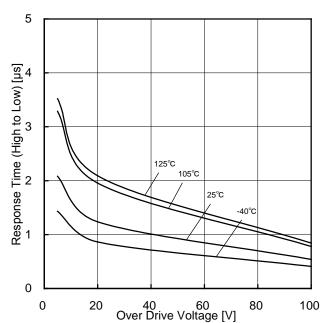


Figure 86.
Response Time (High to Low)
vs Over Drive Voltage
(VCC=5V, V<sub>RL</sub>=5V, R<sub>L</sub>=5.1kΩ)

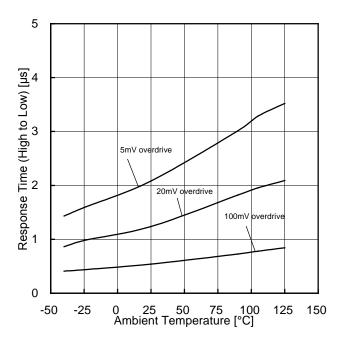


Figure 87. Response Time (High to Low) vs Ambient Temperature (VCC=5V,  $V_{RL}$ =5V,  $R_L$ =5.1k $\Omega$ )

(\*)The above characteristics are measurements of typical sample, they are not guaranteed. BA2903: -40°C to +125°C BA2903S: -40°C to +105°C BA2903W: -40°C to +125°C

OBA2901xx, BA2901Sxx

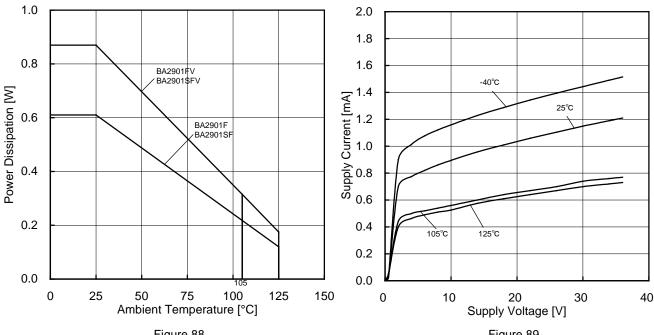
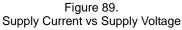


Figure 88.

Power Dissipation vs Ambient Temperature (Derating Curve)

(Refer to the following operating temperature)



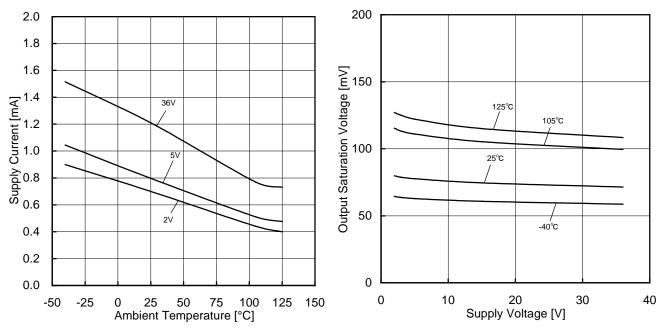


Figure 90.
Supply Current vs Ambient Temperature

Figure 91.

Output Saturation Voltage vs Supply Voltage  $(I_{OL}=4mA)$ 

(\*)The above characteristics are measurements of typical sample, they are not guaranteed. BA2901 : -40°C to +125°C BA2901S : -40°C to +105°C

OBA2901xx, BA2901Sxx

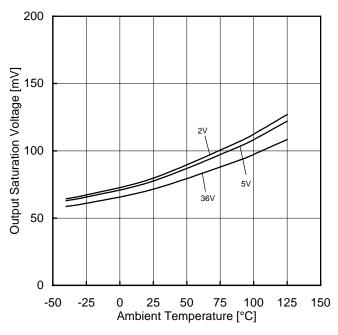


Figure 92. Output Saturation Voltage vs Ambient Temperature ( $I_{OL}$ =4mA)

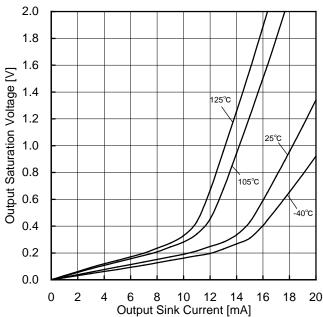


Figure 93.
Output Saturation Voltage vs
Output Sink Current
(VCC=5V)

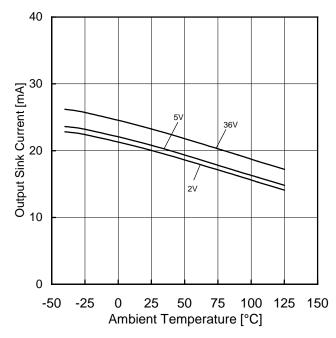


Figure 94.
Output Sink Current vs Ambient Temperature
(OUT=1.5V)

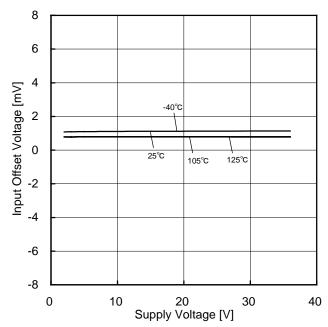


Figure 95.
Input Offset Voltage vs Supply Voltage

(\*)The above characteristics are measurements of typical sample, they are not guaranteed. BA2901 : -40°C to +125°C BA2901S : -40°C to +105°C

OBA2901xx, BA2901Sxx

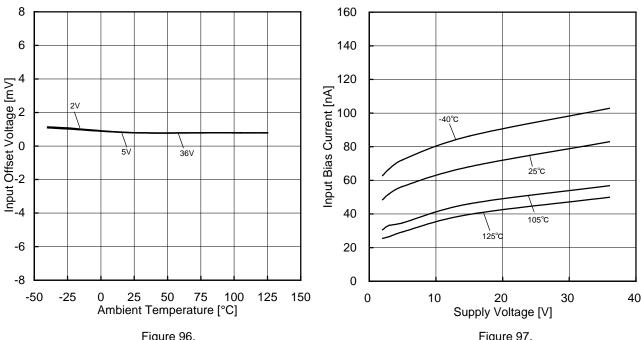
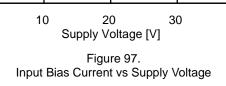
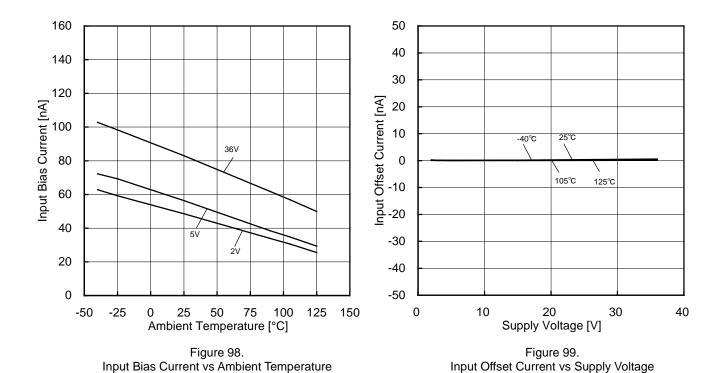


Figure 96. Input Offset Voltage vs Ambient Temperature

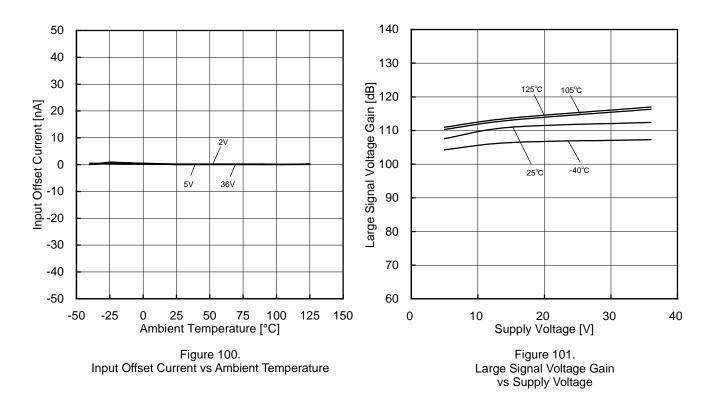


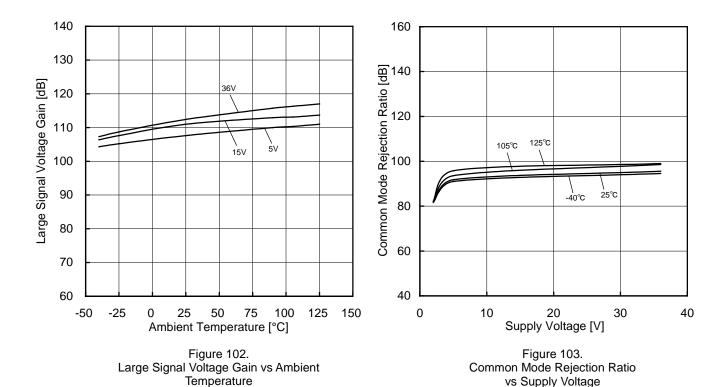


(\*)The above characteristics are measurements of typical sample, they are not guaranteed. BA2901 : -40°C to +125°C BA2901S : -40°C to +105°C

# **Typical Performance Curves - continued**

OBA2901xx, BA2901Sxx





(\*)The above characteristics are measurements of typical sample, they are not guaranteed. BA2901 : -40°C to +125°C BA2901S : -40°C to +105°C

# **Typical Performance Curves - continued**

OBA2901xx, BA2901Sxx

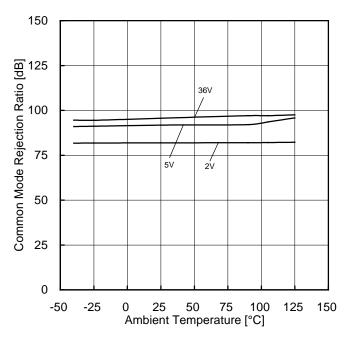


Figure 104.
Common Mode Rejection Ratio vs Ambient
Temperature

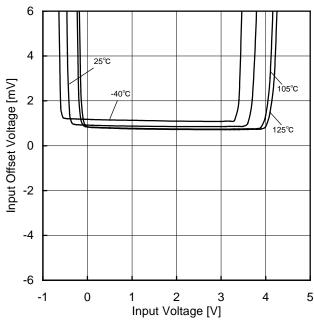


Figure 105.
Input Offset Voltage - Input Voltage (VCC=5V)

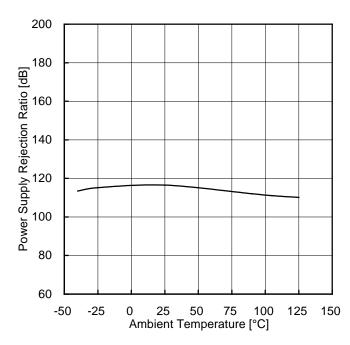
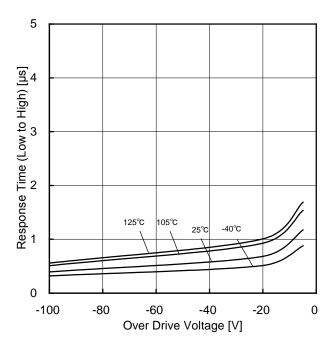


Figure 106.
Power Supply Rejection Ratio vs Ambient
Temperature



 $Figure \ 107. \\ Response \ Time \ (Low \ to \ High) \\ vs \ Over \ Drive \ Voltage \\ (VCC=5V, \ V_{RL}=5V, \ R_L=5.1k\Omega)$ 

(\*)The above characteristics are measurements of typical sample, they are not guaranteed. BA2901 : -40°C to  $\pm$ 125°C BA2901S : -40°C to  $\pm$ 105°C

# **Typical Performance Curves - continued**

OBA2901xx, BA2901Sxx

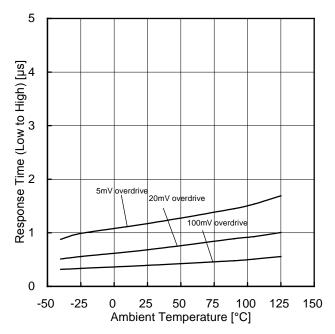


Figure 108.
Response Time (Low to High)
vs Ambient Temperature
(VCC=5V, V<sub>RL</sub>=5V, R<sub>L</sub>=5.1kΩ)

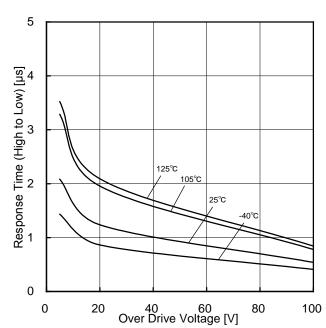


Figure 109.
Response Time (High to Low)
vs Over Drive Voltage
(VCC=5V, V<sub>RL</sub>=5V, R<sub>L</sub>=5.1kΩ)

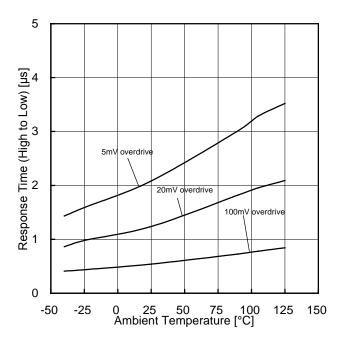


Figure 110. Response Time (High to Low) vs Ambient Temperature (VCC=5V,  $V_{RL}$ =5V,  $R_L$ =5.1k $\Omega$ )

(\*)The above characteristics are measurements of typical sample, they are not guaranteed. BA2901 : -40°C to +125°C BA2901S : -40°C to +105°C

# **Application Information**

# **NULL** method condition for Test Circuit1

VCC.	VEE.	EK.	VICM	Unit:	V.	VRL=VCC

								٧O	O, VLL	, LIX, V	ICM OTHE	. v, vi	(L-VCC
Parameter V <sub>F</sub>		S1	S2	S3	BA1	BA10393 / BA10339		BA8391 / BA2903 / BA2901			Calculation		
Farameter	V <sub>F</sub>	31	32	33	VCC	VEE	EK	V <sub>ICM</sub>	VCC	VEE	EK	V <sub>ICM</sub>	Calculation
Input Offset Voltage	V <sub>F1</sub>	ON	ON	ON	5	0	-1.4	0	5 to 36	0	-1.4	0	1
Input Offset Current	V <sub>F2</sub>	OFF	OFF	ON	5	0	-1.4	0	5	0	-1.4	0	2
Input Pigg Current	$V_{F3}$	OFF	ON	ON	5	0	-1.4	0	5	0	-1.4	0	3
Input Bias Current	$V_{F4}$	ON	OFF	ON	5	0	-1.4	0	5	0	-1.4	0	3
Large Signal Voltage Gain	$V_{F5}$	ON	ON	ON	15	0	-1.4	0	15	0	-1.4	0	4
Large Signal Voltage Galli	$V_{F6}$	ON	OIN	ON	15	0	-11.4	0	15	0	-11.4	0	-

- Calculation -

1. Input Offset Voltage ( $V_{IO}$ )

$$V_{IO} = \frac{|V_{F1}|}{1 + R_F/R_S} [V]$$

2. Input Offset Current (I<sub>IO</sub>)

$$I_{IO} = \frac{|V_{F2}-V_{F1}|}{R_{I} \times (1+R_{F}/R_{S})}$$
 [A]

3. Input Bias Current (I<sub>B</sub>)

$$I_{B} \ = \frac{|V_{F4}\text{-}V_{F3}|}{2 \times R_{I} \times (1 + R_{F}/R_{S})} \quad [A]$$

4. Large Signal Voltage Gain (A<sub>V</sub>)

$$A_V = 20Log \frac{\Delta EK \times (1+R_F/R_S)}{|V_{FS}-V_{FS}|}$$
 [dB]

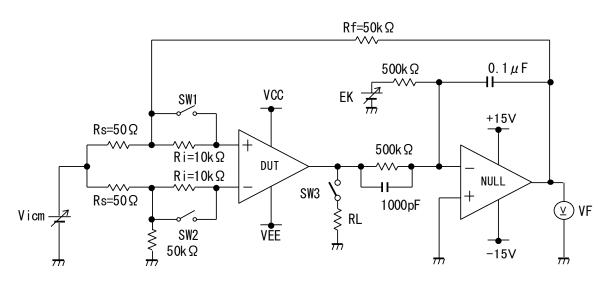


Figure 111. Test Circuit1 (One Channel Only)

## Application Information - continued Switch Condition for Test Circuit 2

CW	SW	SW	SW	SW	SW	SW	SW	
SW No.		1	2	3	4	5	6	7
Supply Current		OFF						
Output Sink Current	VOL=1.5V	OFF	ON	ON	OFF	OFF	OFF	ON
Saturation Voltage	IOL=4mA	OFF	ON	ON	OFF	ON	ON	OFF
Output Leakage Current	VOH=36V	OFF	ON	ON	OFF	OFF	OFF	ON
Response Time	$R_L$ =5.1k $\Omega$ , $V_{RL}$ =5 $V$	ON	OFF	ON	ON	OFF	OFF	OFF

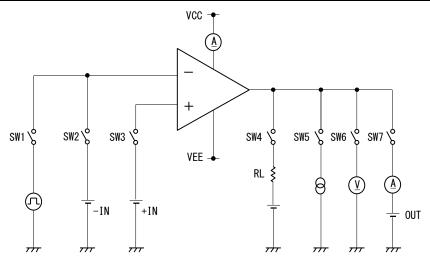


Figure 112. Test Circuit 2 (One Channel Only)

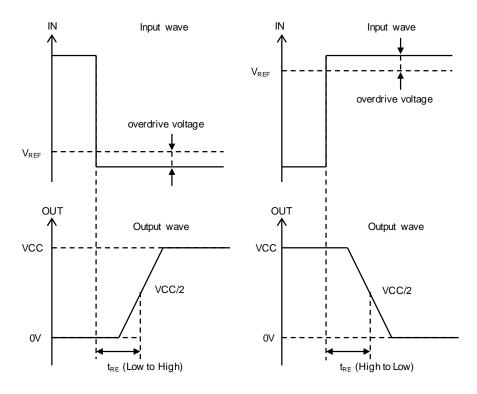


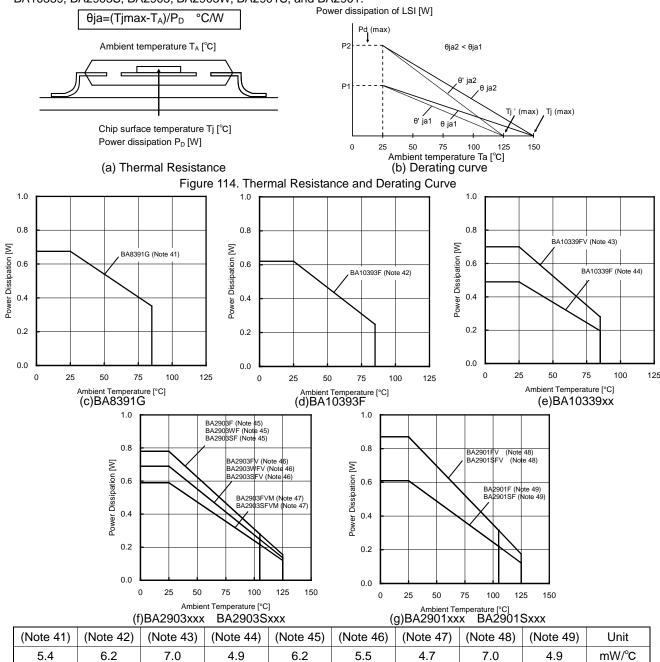
Figure 113. Response Time

#### **Power Dissipation**

Power dissipation (total loss) indicates the power that can be consumed by IC at  $T_A=25^{\circ}\text{C}$  (normal temperature).IC is heated when it consumed power, and the temperature of IC chip becomes higher than ambient temperature. The temperature that can be accepted by IC chip depends on circuit configuration, manufacturing process, and consumable power is limited. Power dissipation is determined by the temperature allowed in IC chip (maximum junction temperature) and thermal resistance of package (heat dissipation capability). The maximum junction temperature is typically equal to the maximum value in the storage temperature range. Heat generated by consumed power of IC radiates from the mold resin or lead frame of the package. The parameter which indicates this heat dissipation capability (hardness of heat release)is called thermal resistance, represented by the symbol  $\theta$  of C/W.The temperature of IC inside the package can be estimated by this thermal resistance. Figure 114 (a) shows the model of thermal resistance of the package. Thermal resistance  $\theta$ , ambient temperature  $T_A$ , maximum junction temperature  $T_A$ , and power dissipation  $P_D$  can be calculated by the equation below:

$$\theta_{ia} = (T_{imax}-T_{A})/P_{D}$$
 °C/W • • • • • (I)

Derating curve in Figure 114 (b) indicates power that can be consumed by IC with reference to ambient temperature. Power that can be consumed by IC begins to attenuate at certain ambient temperature. This gradient is determined by thermal resistance θja. Thermal resistance θja depends on chip size, power consumption, package, ambient temperature, package condition, wind velocity, etc even when the same of package is used. Thermal reduction curve indicates a reference value measured at a specified condition. Figure 115 (c) to (g) shows a derating curve for an example of BA8391, BA10393, BA2903S, BA2903W, BA2901S, and BA2901.



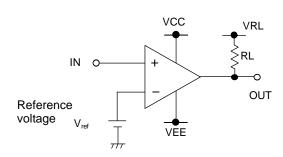
When using the unit above Ta=25°C, subtract the value above per degree°C.

Permissible dissipation is the value when FR4 glass epoxy board 70mm ×1.6mm (cooper foil area below 3%) is mounted.

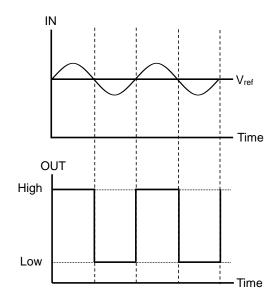
Figure 115. Derating Curve

# **Example of Circuit**

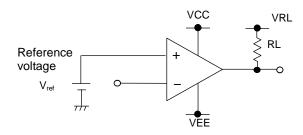
OReference voltage is V<sub>IN-</sub>



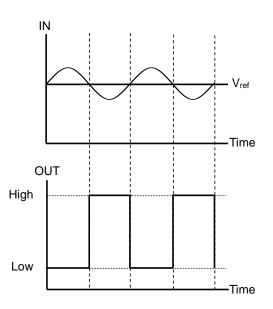
While input voltage is bigger than reference voltage, output voltage is high. While input voltage is smaller than reference voltage, output voltage is low.



OReference voltage is  $V_{\text{IN+}}$ 



While input voltage is smaller than reference voltage, output voltage is high. While input voltage is bigger than reference voltage, output voltage is low.



#### **Operational Notes**

#### 1. Reverse Connection of Power Supply

Connecting the power supply in reverse polarity can damage the IC. Take precautions against reverse polarity when connecting the power supply, such as mounting an external diode between the power supply and the IC's power supply terminals.

## 2. Power Supply Lines

Design the PCB layout pattern to provide low impedance ground and supply lines. Separate the ground and supply lines of the digital and analog blocks to prevent noise in the ground and supply lines of the digital block from affecting the analog block. Furthermore, connect a capacitor to ground at all power supply pins. Consider the effect of temperature and aging on the capacitance value when using electrolytic capacitors.

#### 3. Ground Voltage

Ensure that no pins are at a voltage below that of the ground pin at any time, even during transient condition.

### 4. Ground Wiring Pattern

When using both small-signal and large-current ground traces, the two ground traces should be routed separately but connected to a single ground at the reference point of the application board to avoid fluctuations in the small-signal ground caused by large currents. Also ensure that the ground traces of external components do not cause variations on the ground voltage. The ground lines must be as short and thick as possible to reduce line impedance.

#### 5. Thermal Consideration

Should by any chance the power dissipation rating be exceeded, the rise in temperature of the chip may result in deterioration of the properties of the chip. In case of exceeding this absolute maximum rating, increase the board size and copper area to prevent exceeding the Pd rating.

#### 6. Recommended Operating Conditions

These conditions represent a range within which the expected characteristics of the IC can be approximately obtained. The electrical characteristics are guaranteed under the conditions of each parameter.

#### 7. Inrush Current

When power is first supplied to the IC, it is possible that the internal logic may be unstable and inrush current may flow instantaneously due to the internal powering sequence and delays, especially if the IC has more than one power supply. Therefore, give special consideration to power coupling capacitance, power wiring, width of ground wiring, and routing of connections.

# 8. Operation Under Strong Electromagnetic Field

Operating the IC in the presence of a strong electromagnetic field may cause the IC to malfunction.

#### 9. Testing on Application Boards

When testing the IC on an application board, connecting a capacitor directly to a low-impedance output pin may subject the IC to stress. Always discharge capacitors completely after each process or step. The IC's power supply should always be turned off completely before connecting or removing it from the test setup during the inspection process. To prevent damage from static discharge, ground the IC during assembly and use similar precautions during transport and storage.

#### 10. Inter-pin Short and Mounting Errors

Ensure that the direction and position are correct when mounting the IC on the PCB. Incorrect mounting may result in damaging the IC. Avoid nearby pins being shorted to each other especially to ground. Inter-pin shorts could be due to many reasons such as metal particles, water droplets (in very humid environment) and unintentional solder bridge deposited in between pins during assembly to name a few.

## Operational Notes - continued

#### 11. Regarding Input Pins of the IC

This monolithic IC contains P+ isolation and P substrate layers between adjacent elements in order to keep them isolated. P-N junctions are formed at the intersection of the P layers with the N layers of other elements, creating a parasitic diode or transistor. For example (refer to figure below):

When GND > Pin A and GND > Pin B, the P-N junction operates as a parasitic diode.

When GND > Pin B, the P-N junction operates as a parasitic transistor.

Parasitic diodes inevitably occur in the structure of the IC. The operation of parasitic diodes can result in mutual interference among circuits, operational faults, or physical damage. Therefore, conditions that cause these diodes to operate, such as applying a voltage lower than the GND voltage to an input pin (and thus to the P substrate) should be avoided.

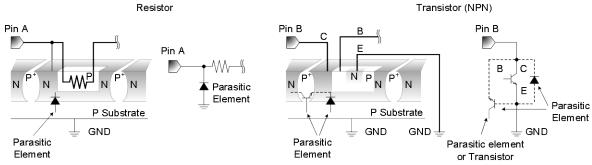


Figure 116. Example of Monolithic IC Structure

#### 12. Unused Circuits

When there are unused circuits it is recommended that they be connected as in Figure 117, setting the non-inverting input terminal to a potential within the in-phase input voltage range ( $V_{ICR}$ ).

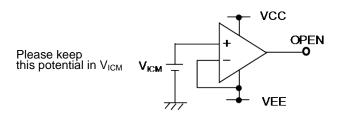


Figure 117. Disable Circuit Example

## 13. Ceramic Capacitor

When using a ceramic capacitor, determine the dielectric constant considering the change of capacitance with temperature and the decrease in nominal capacitance due to DC bias and others.

#### 14. Input Terminal Voltage

(BA8391G / BA2903xxxx / BA2901xxx) Applying VEE + 36V to the input terminal is possible without causing deterioration of the electrical characteristics or destruction, irrespective of the supply voltage. However, this does not ensure normal circuit operation. Please note that the circuit operates normally only when the input voltage is within the common mode input voltage range of the electric characteristics.

### 15. Power Supply (single / split)

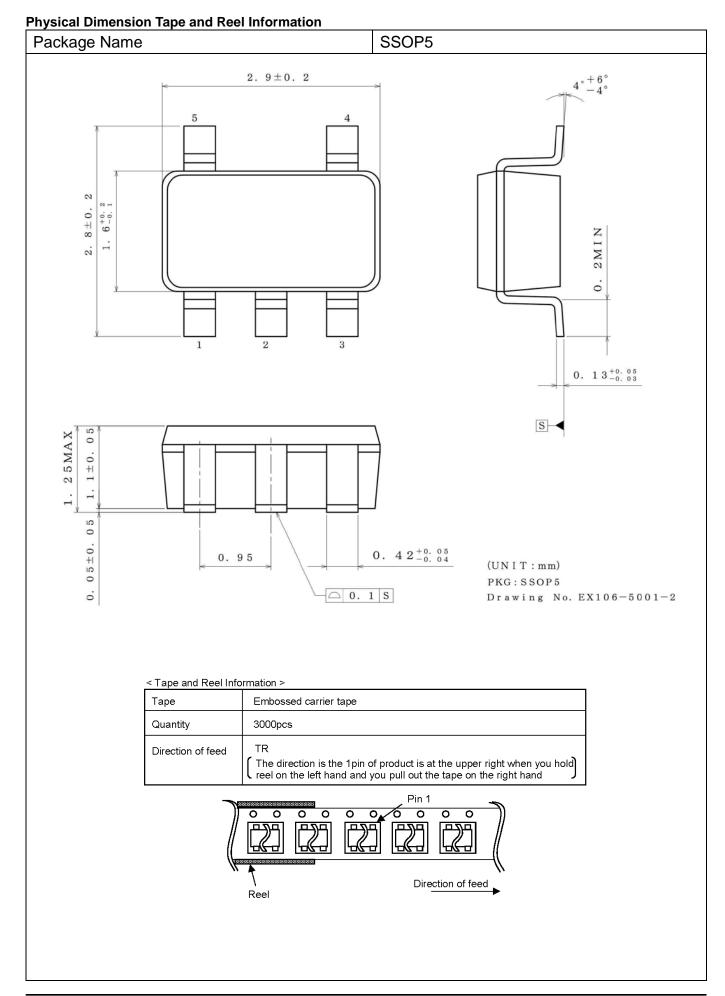
The comparators when the specified voltage supplied is between VCC and VEE. Therefore, the single supply comparators can be used as a dual supply comparators as well.

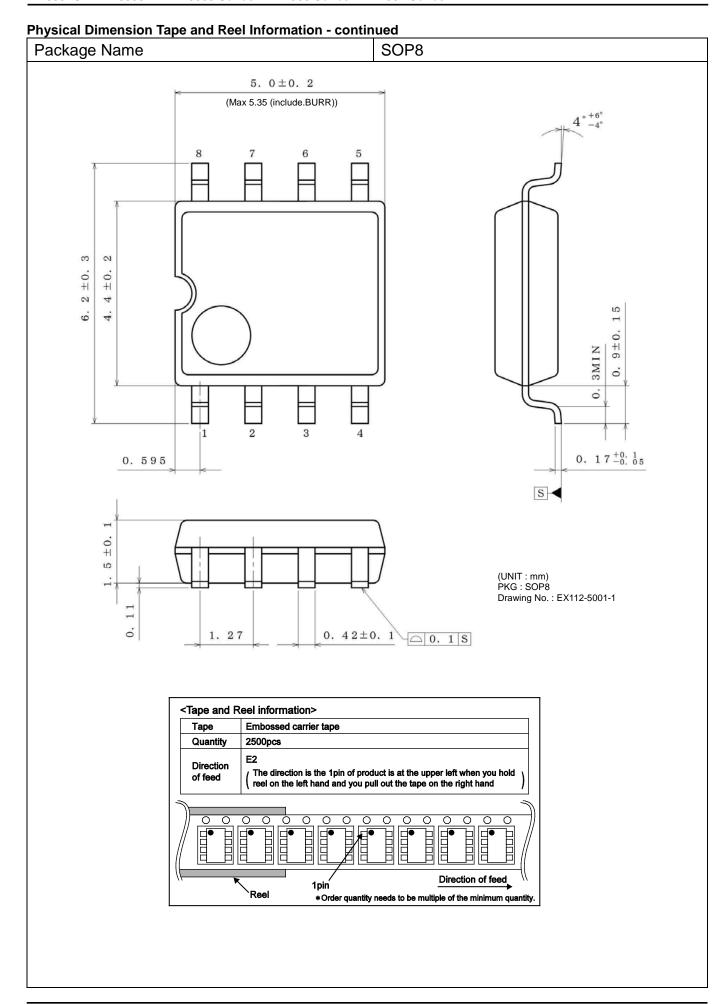
## 16. Terminal short-circuits

When the output and VCC terminals are shorted, excessive output current may flow, resulting in undue heat generation and, subsequently, destruction.

#### 17. IC Handling

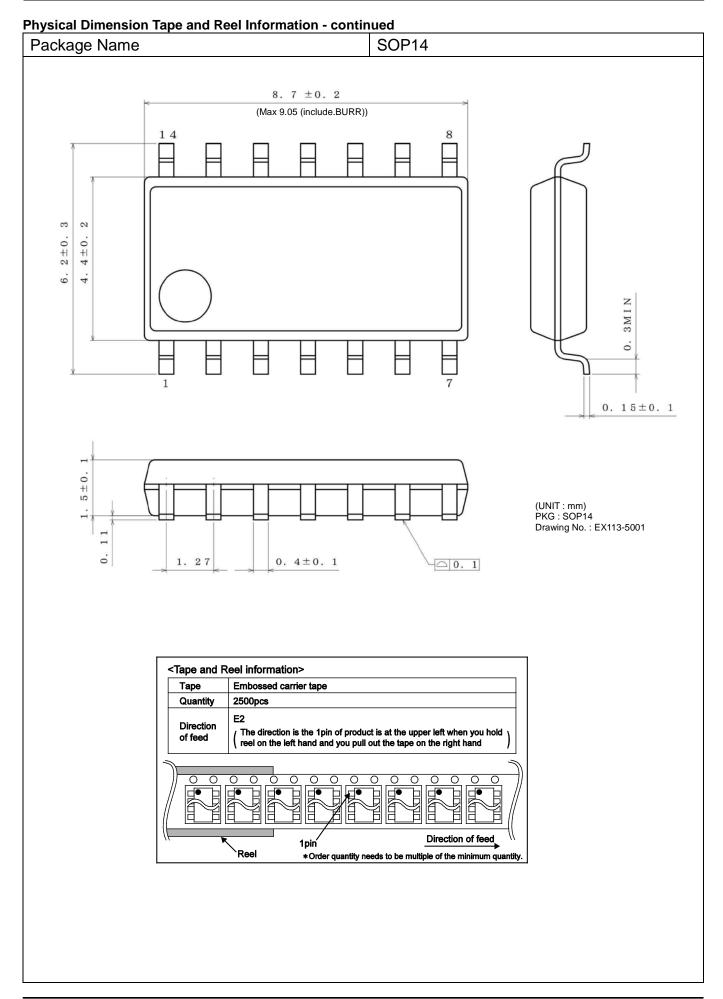
Applying mechanical stress to the IC by deflecting or bending the board may cause fluctuations in the electrical characteristics due to piezo resistance effects.





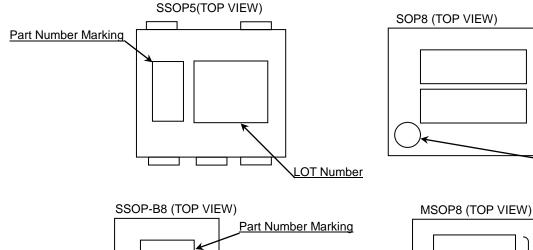
**Physical Dimension Tape and Reel Information - continued** Package Name SSOP-B8 3.  $0 \pm 0$ . 2 (Max3. 35 (include. BURR) 4 ± 0. 3MIN o. 0. 15±0. 1 S o. 0. 1 S 0.  $22^{+0.06}_{-0.04}$   $\bigcirc$  0. 08(0.52) 0.65 (UNIT:mm) PKG:SSOP-B8 Drawing No. EX151-5002 <Tape and Reel information> Таре Embossed carrier tape 2500pcs Quantity Direction The direction is the 1pin of product is at the upper left when you hold reel on the left hand and you pull out the tape on the right hand of feed Direction of feed 1pin \*Order quantity needs to be multiple of the minimum quantity.

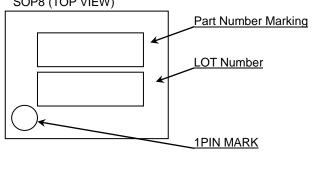
**Physical Dimension Tape and Reel Information - continued** Package Name MSOP8 2. 9±0. 1 Max 3. 25 (include. BURR) 4.  $0 \pm 0$ . 0 0 0.475 1PIN MARK  $0.\ \ 1\ 4\ 5\ ^{+\ 0.\ \ 0\ 5}_{-\ 0.\ \ 0\ 3}$ S 9MAX 0.5 0.5  $0.8\pm0$  $0.75\pm0.$  $0.22^{\,+\,0.05}_{\,-\,0.04}$ (UNIT:mm) 0.65 PKG: MSOP8 ○ 0. 08 S 0 Drawing No. EX181-5002 <Tape and Reel information> Embossed carrier tape Tape Quantity 3000pcs Direction The direction is the 1pin of product is at the upper right when you hold reel on the left hand and you pull out the tape on the right hand of feed Direction of feed Reel \*Order quantity needs to be multiple of the minimum quantity.

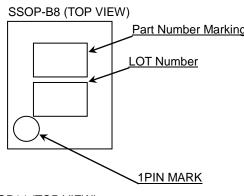


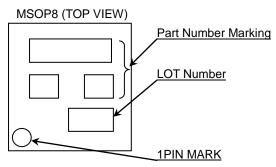
**Physical Dimension Tape and Reel Information - continued** Package Name SSOP-B14 5.  $0 \pm 0$ . 2 (Max 5. 35 (include. BURR) 3MIN 0.  $15\pm0.1$ (UNIT:mm) o. 0.65 0. 22±0. 1 0. 08 M PKG:SSOP-B14 Drawing No. EX152-5002 0. 1 <Tape and Reel information> Tape Embossed carrier tape Quantity 2500pcs **E2** Direction ( The direction is the 1pin of product is at the upper left when you hold reel on the left hand and you pull out the tape on the right hand of feed Direction of feed 1pin \*Order quantity needs to be multiple of the minimum quantity

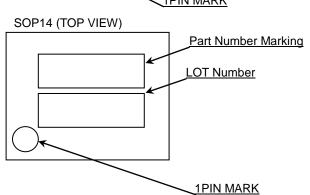
# **Marking Diagrams**

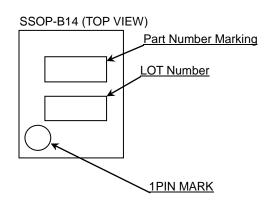












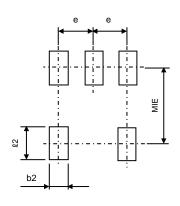
Product Name		Package Type	Marking	
BA8391	G	SSOP5	D6	
BA10393	F	SOP8	10393	
DA40220	F	SOP14	BA10339F	
BA10339	FV	SSOP-B14	339	
	F	SOP8		
BA2903	FV	SSOP-B8		
	FVM	MSOP8	2903	
D A 2002/A/	F	SOP8		
BA2903W	FV	SSOP-B8		
	F	SOP8	2903S	
BA2903S	FV	SSOP-B8	03S	
	FVM	MSOP8	2903S	
D A 2004	F	SOP14	BA2901F	
BA2901	FV	SSOP-B14	2901	
DA20016	F	SOP14	2004.6	
BA2901S	FV	SSOP-B14	2901S	

# **Land Pattern Data**

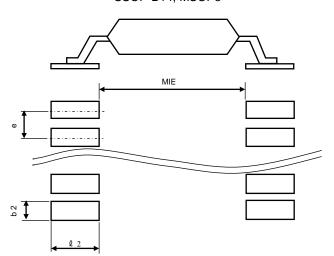
## All dimensions in mm

PKG	Land Pitch e	Land Space MIE	Land Length ≧ℓ 2	Land Width b2
SSOP5	0.95	2.4	1.0	0.6
SOP8 SOP14	1.27	4.60	1.10	0.76
SSOP-B8 SSOP-B14	0.65	4.60	1.20	0.35
MSOP8	0.65	2.62	0.99	0.35





SOP8, SOP14, SSOP-B8 SSOP-B14, MSOP8



# **Revision History**

•	* 131011 1 113t01 <b>y</b>							
	Date	Revision	Changes					
	23.Aug.2013	001	lew Release					
	27.Nov.2013	002	Add the dB notation in Large Signal Voltage Gain					
	11.Dec.2013	003	Input offset voltage unit is changed from mA to mV in Page.1.					
	05.Jun.2015	004	Corrections. Update of Operational Notes					

# **Notice**

#### **Precaution on using ROHM Products**

1. Our Products are designed and manufactured for application in ordinary electronic equipments (such as AV equipment, OA equipment, telecommunication equipment, home electronic appliances, amusement equipment, etc.). If you intend to use our Products in devices requiring extremely high reliability (such as medical equipment (Note 1), transport equipment, traffic equipment, aircraft/spacecraft, nuclear power controllers, fuel controllers, car equipment including car accessories, safety devices, etc.) and whose malfunction or failure may cause loss of human life, bodily injury or serious damage to property ("Specific Applications"), please consult with the ROHM sales representative in advance. Unless otherwise agreed in writing by ROHM in advance, ROHM shall not be in any way responsible or liable for any damages, expenses or losses incurred by you or third parties arising from the use of any ROHM's Products for Specific Applications.

(Note1) Medical Equipment Classification of the Specific Applications

JAPAN	USA	EU	CHINA	
CLASSⅢ	CLASSⅢ	CLASS II b	CLASSIII	
CLASSIV	CLASSIII	CLASSⅢ	CLASSIII	

- 2. ROHM designs and manufactures its Products subject to strict quality control system. However, semiconductor products can fail or malfunction at a certain rate. Please be sure to implement, at your own responsibilities, adequate safety measures including but not limited to fail-safe design against the physical injury, damage to any property, which a failure or malfunction of our Products may cause. The following are examples of safety measures:
  - [a] Installation of protection circuits or other protective devices to improve system safety
  - [b] Installation of redundant circuits to reduce the impact of single or multiple circuit failure
- 3. Our Products are designed and manufactured for use under standard conditions and not under any special or extraordinary environments or conditions, as exemplified below. Accordingly, ROHM shall not be in any way responsible or liable for any damages, expenses or losses arising from the use of any ROHM's Products under any special or extraordinary environments or conditions. If you intend to use our Products under any special or extraordinary environments or conditions (as exemplified below), your independent verification and confirmation of product performance, reliability, etc, prior to use, must be necessary:
  - [a] Use of our Products in any types of liquid, including water, oils, chemicals, and organic solvents
  - [b] Use of our Products outdoors or in places where the Products are exposed to direct sunlight or dust
  - [c] Use of our Products in places where the Products are exposed to sea wind or corrosive gases, including Cl<sub>2</sub>, H<sub>2</sub>S, NH<sub>3</sub>, SO<sub>2</sub>, and NO<sub>2</sub>
  - [d] Use of our Products in places where the Products are exposed to static electricity or electromagnetic waves
  - [e] Use of our Products in proximity to heat-producing components, plastic cords, or other flammable items
  - [f] Sealing or coating our Products with resin or other coating materials
  - [g] Use of our Products without cleaning residue of flux (even if you use no-clean type fluxes, cleaning residue of flux is recommended); or Washing our Products by using water or water-soluble cleaning agents for cleaning residue after soldering
  - [h] Use of the Products in places subject to dew condensation
- 4. The Products are not subject to radiation-proof design.
- 5. Please verify and confirm characteristics of the final or mounted products in using the Products.
- 6. In particular, if a transient load (a large amount of load applied in a short period of time, such as pulse. is applied, confirmation of performance characteristics after on-board mounting is strongly recommended. Avoid applying power exceeding normal rated power; exceeding the power rating under steady-state loading condition may negatively affect product performance and reliability.
- 7. De-rate Power Dissipation (Pd) depending on Ambient temperature (Ta). When used in sealed area, confirm the actual ambient temperature.
- 8. Confirm that operation temperature is within the specified range described in the product specification.
- 9. ROHM shall not be in any way responsible or liable for failure induced under deviant condition from what is defined in this document.

#### Precaution for Mounting / Circuit board design

- 1. When a highly active halogenous (chlorine, bromine, etc.) flux is used, the residue of flux may negatively affect product performance and reliability.
- 2. In principle, the reflow soldering method must be used on a surface-mount products, the flow soldering method must be used on a through hole mount products. If the flow soldering method is preferred on a surface-mount products, please consult with the ROHM representative in advance.

For details, please refer to ROHM Mounting specification

### **Precautions Regarding Application Examples and External Circuits**

- 1. If change is made to the constant of an external circuit, please allow a sufficient margin considering variations of the characteristics of the Products and external components, including transient characteristics, as well as static characteristics.
- 2. You agree that application notes, reference designs, and associated data and information contained in this document are presented only as guidance for Products use. Therefore, in case you use such information, you are solely responsible for it and you must exercise your own independent verification and judgment in the use of such information contained in this document. ROHM shall not be in any way responsible or liable for any damages, expenses or losses incurred by you or third parties arising from the use of such information.

#### **Precaution for Electrostatic**

This Product is electrostatic sensitive product, which may be damaged due to electrostatic discharge. Please take proper caution in your manufacturing process and storage so that voltage exceeding the Products maximum rating will not be applied to Products. Please take special care under dry condition (e.g. Grounding of human body / equipment / solder iron, isolation from charged objects, setting of lonizer, friction prevention and temperature / humidity control).

# **Precaution for Storage / Transportation**

- 1. Product performance and soldered connections may deteriorate if the Products are stored in the places where:
  - [a] the Products are exposed to sea winds or corrosive gases, including Cl2, H2S, NH3, SO2, and NO2
  - [b] the temperature or humidity exceeds those recommended by ROHM
  - [c] the Products are exposed to direct sunshine or condensation
  - [d] the Products are exposed to high Electrostatic
- 2. Even under ROHM recommended storage condition, solderability of products out of recommended storage time period may be degraded. It is strongly recommended to confirm solderability before using Products of which storage time is exceeding the recommended storage time period.
- 3. Store / transport cartons in the correct direction, which is indicated on a carton with a symbol. Otherwise bent leads may occur due to excessive stress applied when dropping of a carton.
- 4. Use Products within the specified time after opening a humidity barrier bag. Baking is required before using Products of which storage time is exceeding the recommended storage time period.

### **Precaution for Product Label**

QR code printed on ROHM Products label is for ROHM's internal use only.

#### **Precaution for Disposition**

When disposing Products please dispose them properly using an authorized industry waste company.

#### **Precaution for Foreign Exchange and Foreign Trade act**

Since concerned goods might be fallen under listed items of export control prescribed by Foreign exchange and Foreign trade act, please consult with ROHM in case of export.

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